



“20 years anniversary of the SESAM”

20 years of SESAM modelocked lasers: a success story

Ursula Keller

Department of Physics, Institute for Quantum Electronics,
ETH Zurich, Switzerland

Plenary Talk

*Advanced Laser Technologies, ALT 2012
2.-6. Sept. 2012, Thun, Switzerland*

Ultrafast solid-state laser oscillators: a success story for the last 20 years with no end in sight

U. Keller

How did it all happen?
This is the paper to read ...

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20 years of ultrafast solid-state lasers: invited paper

- Why was it assumed that diode-pumped solid-state lasers cannot be passively modelocked?
- How was the SESAM invented?
- State-of-the-art performance and future outlook.

Solid-state low-loss intracavity saturable absorber for Nd:YLF lasers: an antiresonant semiconductor Fabry–Perot saturable absorber

U. Keller, D. A. B. Miller, G. D. Boyd, T. H. Chiu, J. F. Ferguson, and M. T. Asom

AT&T Bell Laboratories, Crawfords Corner Road, Holmdel, New Jersey 07733

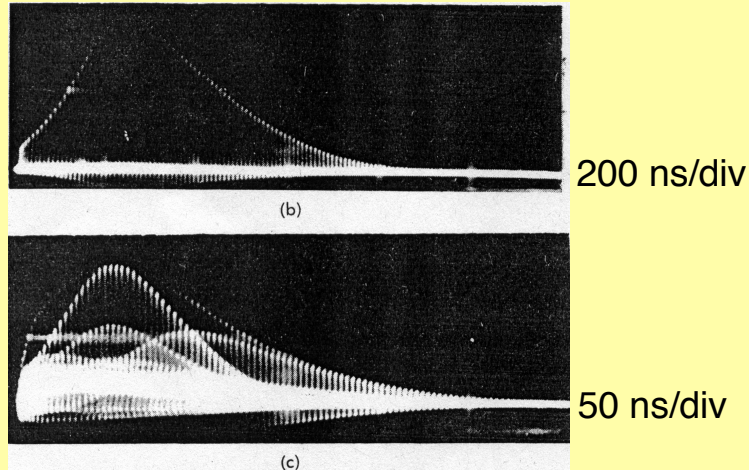
Received November 26, 1991

We introduce a new low-loss fast intracavity semiconductor Fabry–Perot saturable absorber operated at anti-resonance both to start and sustain stable mode locking of a cw-pumped Nd:YLF laser. We achieved a 3.3-ps pulse duration at a 220-MHz repetition rate. The average output power was 700 mW with 2 W of cw pump power from a Ti:sapphire laser. At pump powers of less than 1.6 W the laser self-Q switches and produces 4-ps pulses within a 1.4- μ s Q-switched pulse at an \approx 150-kHz repetition rate determined by the relaxation oscillation of the Nd:YLF laser. Both modes of operation are stable. In terms of coupled-cavity mode locking, the intracavity antiresonant Fabry–Perot saturable absorber corresponds to monolithic resonant passive mode locking.

First SESAM (first design called A-FPSA)
April 1, 1992 (submitted Nov. 26, 1991)

ETH Ultrashort pulse generation with modelocking

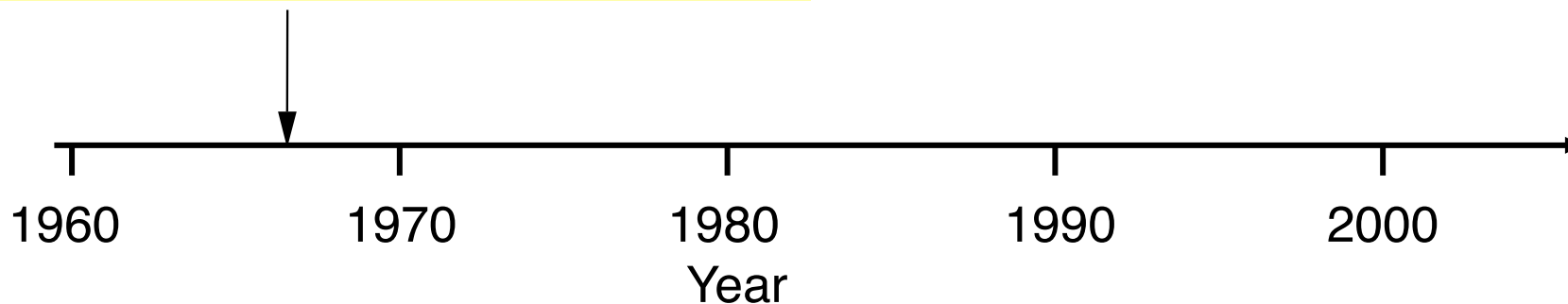
A. J. De Maria, D. A. Stetser, H. Heynau
Appl. Phys. Lett. **8**, 174, 1966



Nd:glass
first passively modelocked laser
Q-switched modelocked

**Q-switching problem
in passively modelocked
solid-state lasers:**

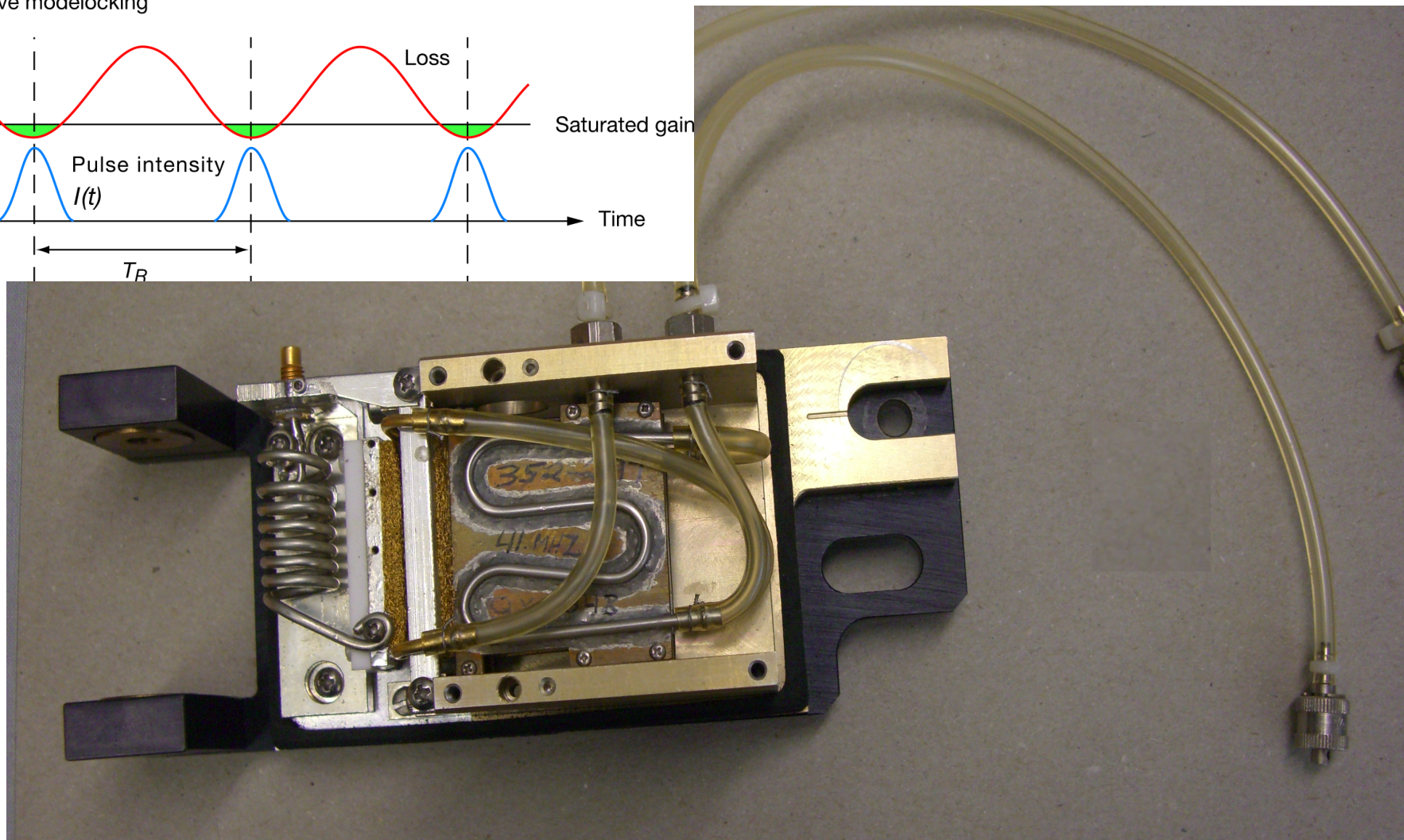
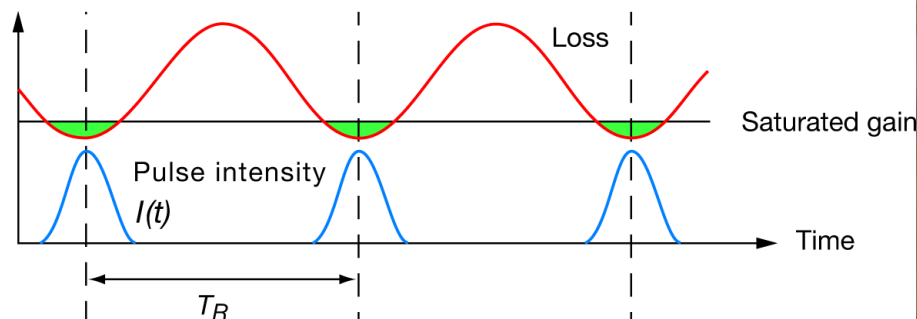
- active modelocking for solid-state lasers
- dye lasers solved the problem



**Flashlamp-pumped
solid-state lasers**

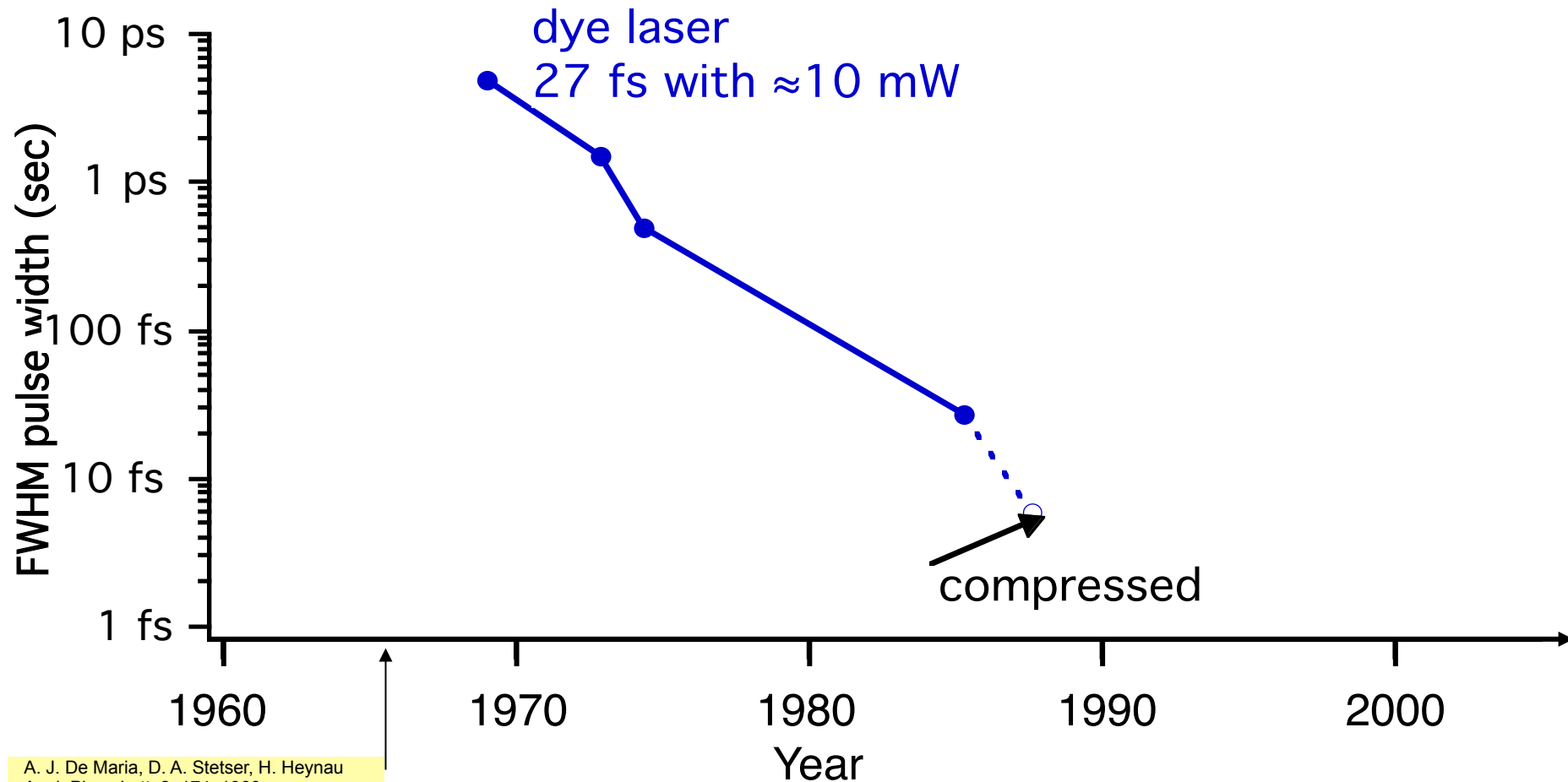
Active Modelocking

Active modelocking

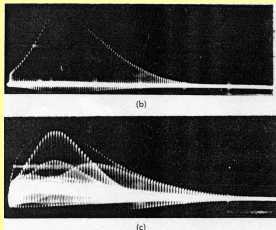


acousto-optic loss modulator
needs RF power and water cooling

ETH Ultrashort pulse generation with modelocking



A. J. De Maria, D. A. Stetser, H. Heynau
Appl. Phys. Lett. 8, 174, 1966



Nd:glass

first passively modelocked laser
Q-switched modelocked

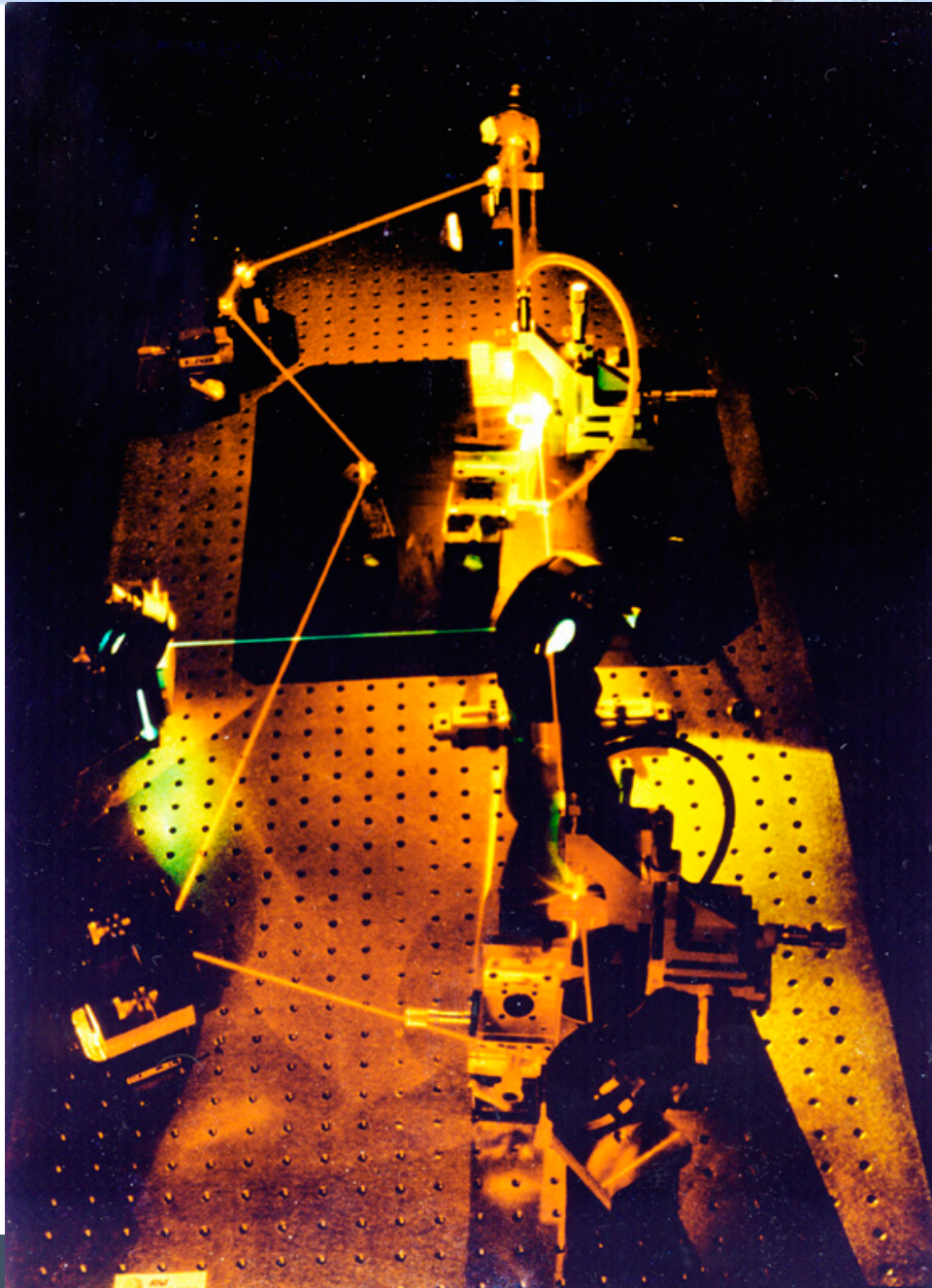
E. P. Ippen, C. V. Shank et al, Appl. Phys. Lett. 21, 348, 1972

J. A. Valdmanis et al., Opt. Lett. 10, 131, 1985 (27 fs)

R. L. Fork et al., Opt. Lett. 12, 483, 1987 (6 fs)



CPM dye laser



Ring laser

Colliding pulse modelocked (CPM) dye laser:

Gain: Rhodamine 6G

Saturable absorber: DODCI

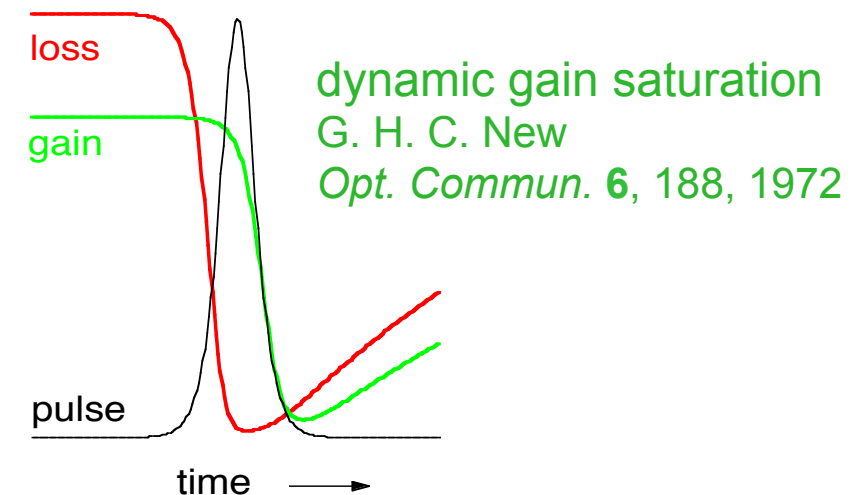
Center wavelength: ≈ 620 nm

Typical pulse duration: > 27 fs

Typical average power: a few 10 mW

J. A. Valdmanis et al.,

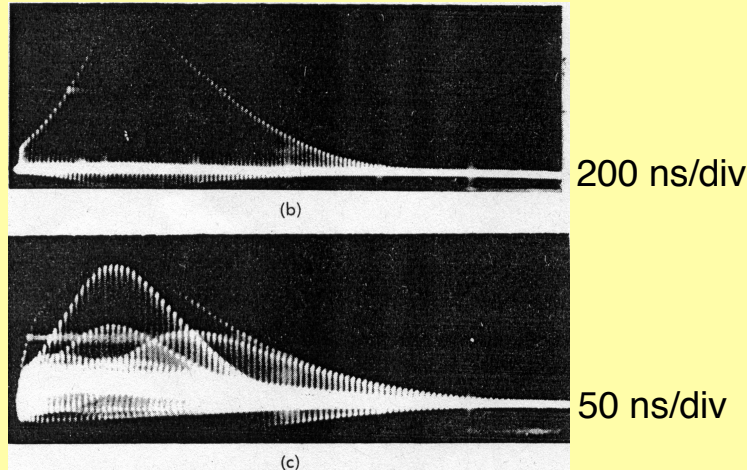
Opt. Lett. **10**, 131, 1985 (27 fs CPM)



*Ursula Keller, Ph.D. student at Stanford
1986 Summer Student at Bell Labs, NJ*

ETH Ultrashort pulse generation with modelocking

A. J. De Maria, D. A. Stetser, H. Heynau
Appl. Phys. Lett. **8**, 174, 1966



Nd:glass
first passively modelocked laser
Q-switched modelocked

**Q-switching instabilities
continued to be a problem until 1992**

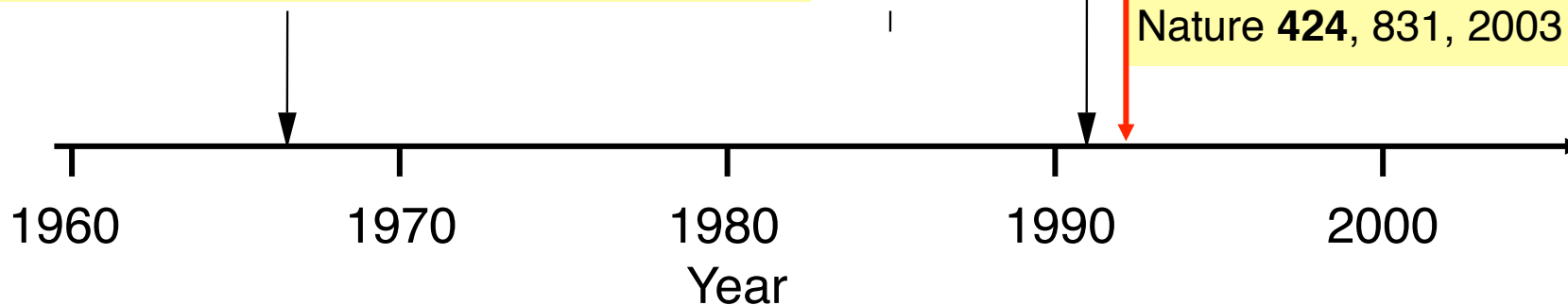
SESAM

First passively modelocked
(diode-pumped) solid-state laser
without Q-switching

U. Keller et al.
Opt. Lett. **17**, 505, 1992

IEEE JSTQE **2**, 435, 1996
Nature **424**, 831, 2003

KLM

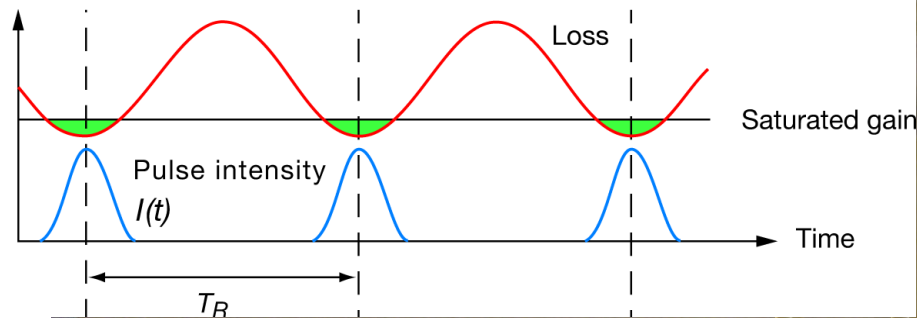


**Flashlamp-pumped
solid-state lasers**

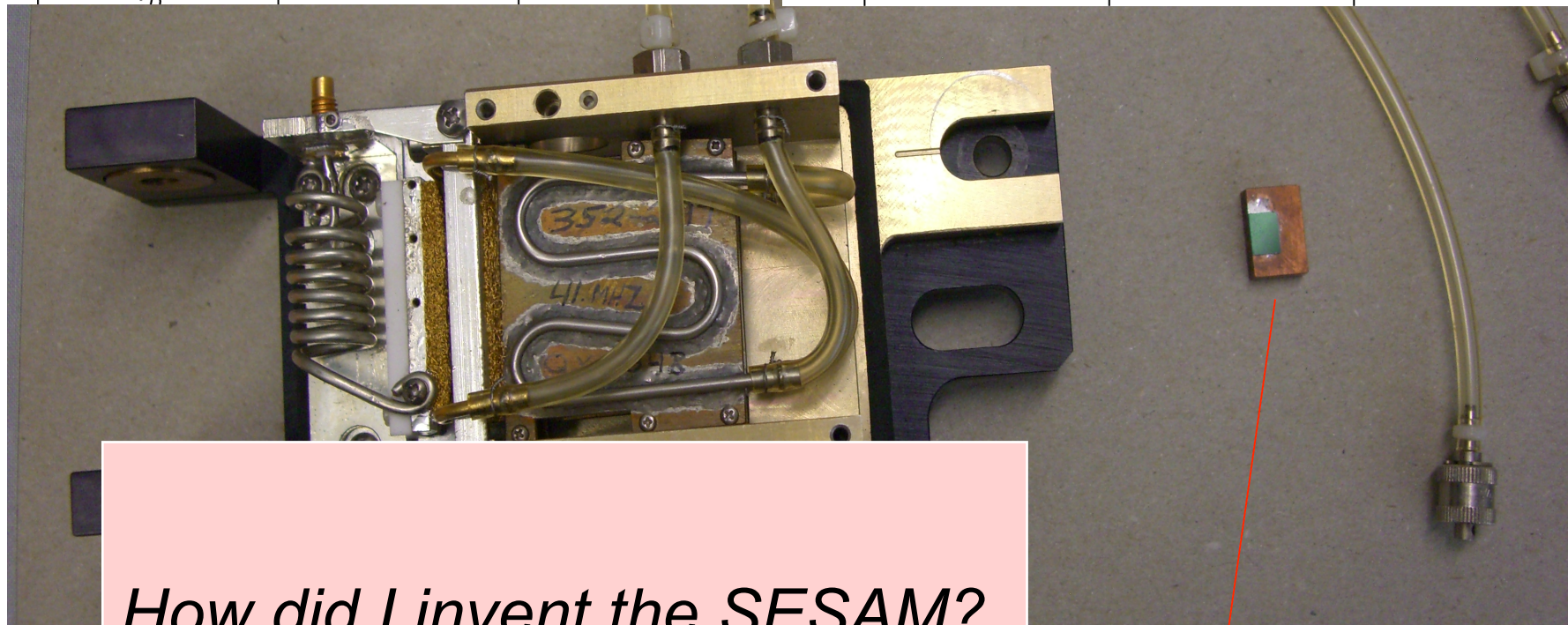
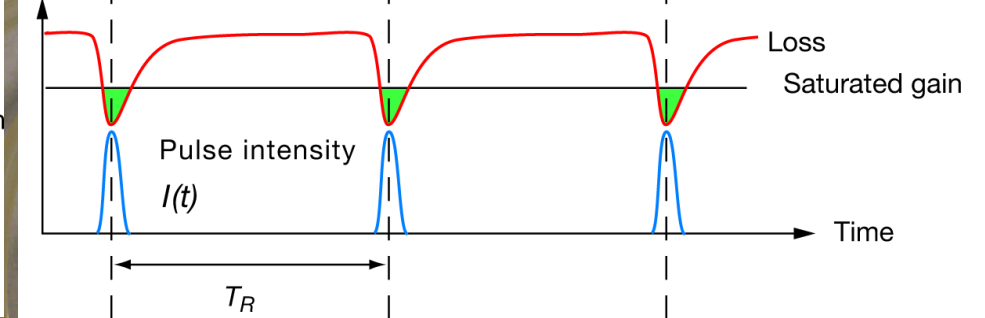
**Diode-pumped solid-state lasers
(first demonstration 1963)**

Innovation: before and after

Active modelocking



Passive modelocking

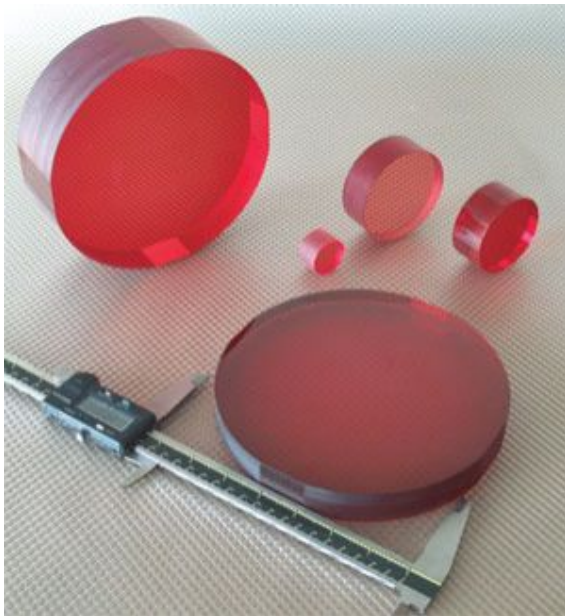
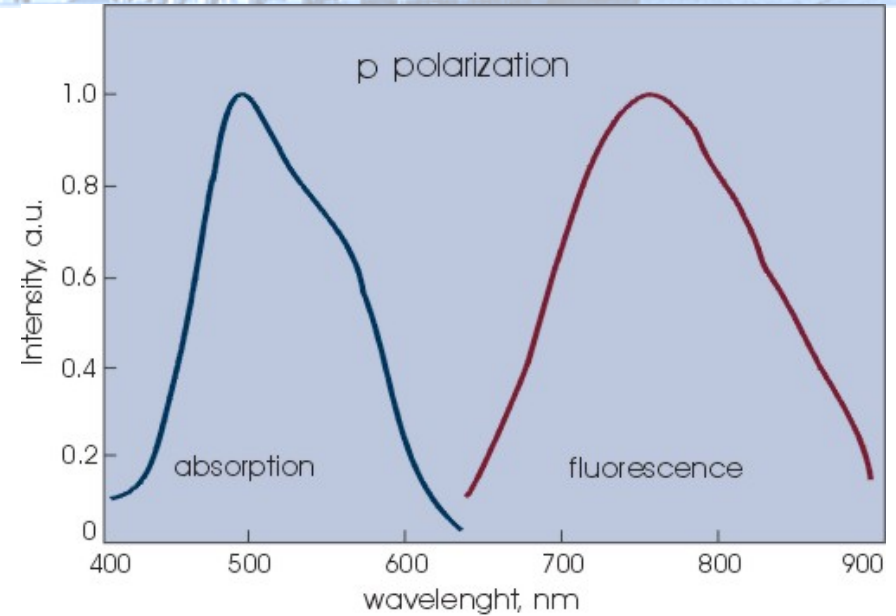
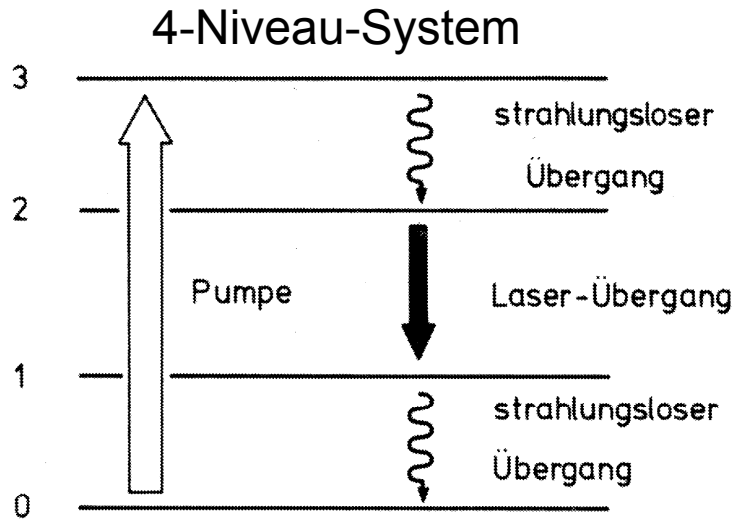


How did I invent the SESAM?

SESAM modelocker

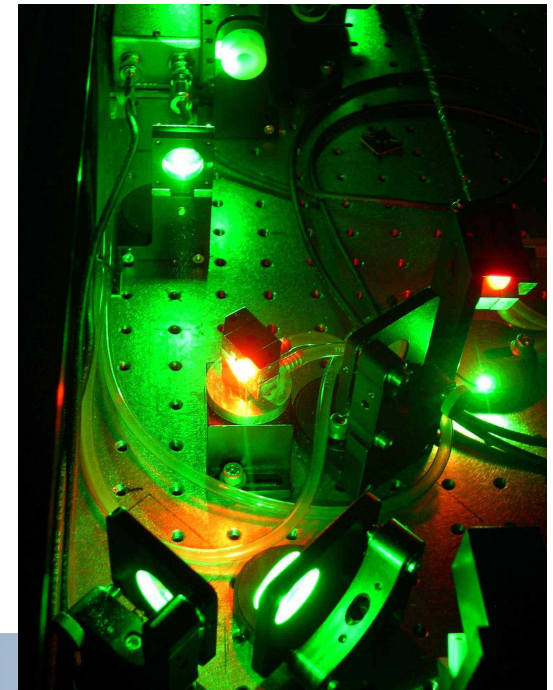
ac
ne

Ti³⁺:Saphir Laser



Ti:Saphir Laser
1982

Peter Moulton
MIT Lincoln Lab



ETH Two experiments that should not have worked ...

“Magic Modelocking”

Postdeadline Paper CLEO 1990
Nr. CPDP10

“modelocked Ti:sapphire laser without
an absorber inside the cavity”
... should not work!

Published result later in:
D. E. Spence, P. N. Kean, W. Sibbett,
Optics Lett. **16**, 42, 1991

Explained modelocking as a “coupled
cavity modelocking effect” between
two transverse modes

Both of them explained later by KLM by Keller et al.

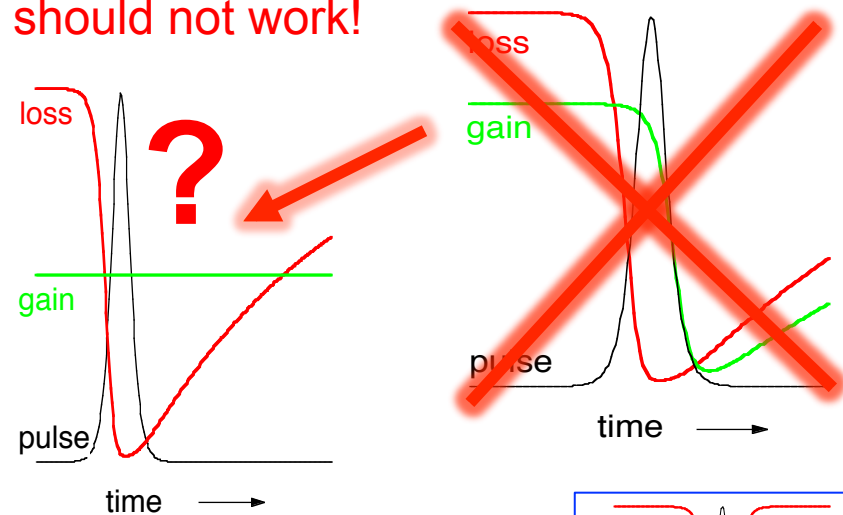
Optics Lett. **16**, 1022, 1991

“CPM Ti:sapphire laser”

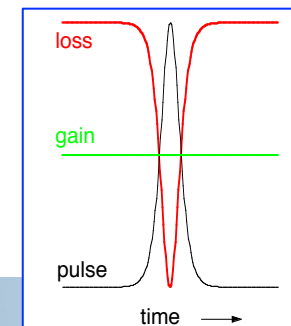
Postdeadline Paper Ultrafast
Phenomena 1990, Nr. PD11

Y. Ishida, N. Sarukura, H. Nakano

“used a dye saturable absorber inside
the CPM Ti:sapphire laser”
... should not work!

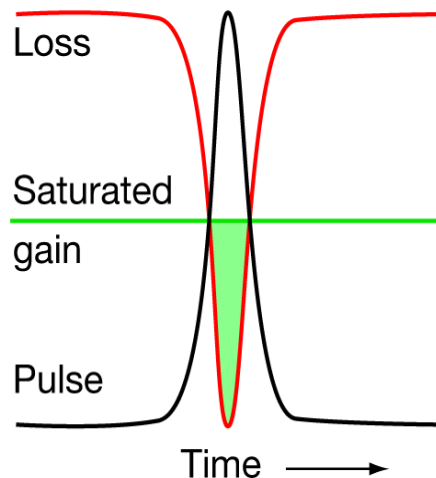
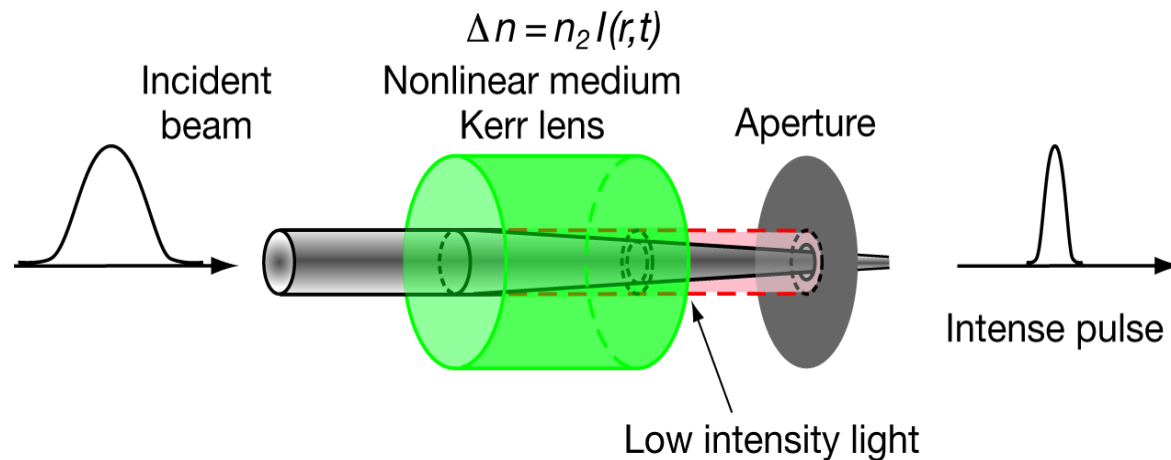


IEEE JQE **28**, 2123, 1992



Kerr Lens Modelocking (KLM)

First Demonstration: D. E. Spence, P. N. Kean, W. Sibbett, *Optics Lett.* **16**, 42, 1991
 Explanation: U. Keller et al., *Optics Lett.* **16**, 1022, 1991



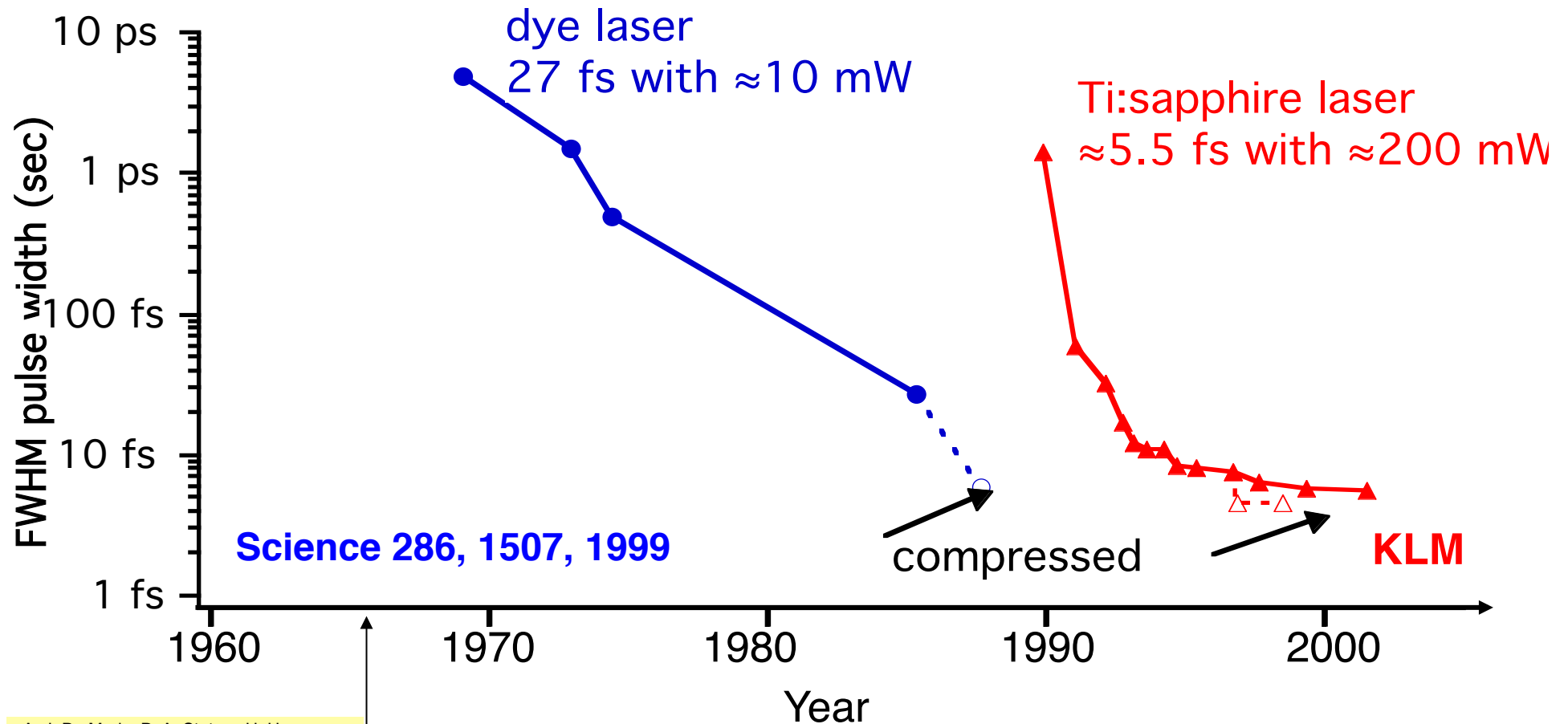
Advantages of KLM

- very fast thus shortest pulses
- very broadband thus broader tunability

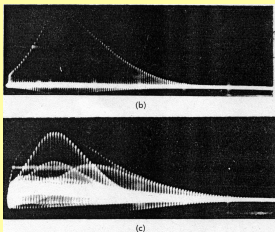
Disadvantages of KLM

- not self-starting
- critical cavity adjustments (operated close to the stability limit)
- saturable absorber coupled to cavity design (limited application)

ETH Ultrashort pulse generation with modelocking



A. J. De Maria, D. A. Stetser, H. Heynau
Appl. Phys. Lett. **8**, 174, 1966



Nd:glass
first passively modelocked laser
Q-switched modelocked

Kerr lens modelocking (KLM):
discovered - initially not understood (“magic modelocking”)

D. E. Spence, P. N. Kean, W. Sibbett, *Opt. Lett.* **16**, 42, 1991

KLM mechanism explained for the first time:

U. Keller et al., *Opt. Lett.* **16**, 1022, 1991



Why did the Sibbett group explain their results as a
“coupled modelocking effect”?

Remember the mind set at that time was:

Passive modelocking of solid-state laser does not work!

... but there was the soliton laser from Linn Mollenauer

1984

January 1984 / Vol. 9, No. 1 / OPTICS LETTERS 13

The soliton laser

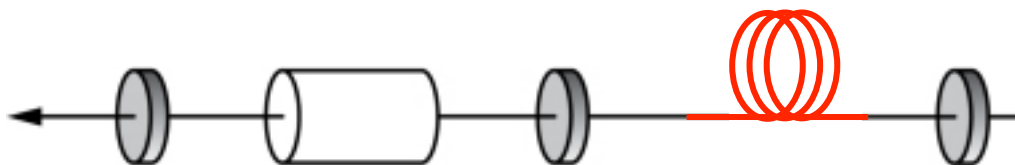
L. F. Mollenauer and R. H. Stolen

Bell Laboratories, Holmdel, New Jersey 07733

Received October 17, 1983; accepted October 28, 1983

By incorporating a length of single-mode, polarization-preserving fiber into the feedback loop of a mode-locked color-center laser ($\lambda \sim 1.4\text{--}1.6\ \mu\text{m}$), we have created a device that we call the soliton laser. Pulse width (2.0 to 0.21 psec obtained to date) is determined by fiber length, in accordance with $N = 2$ soliton behavior. Production of $<50\text{-fsec}$ -wide pulses is indicated for compression in an additional, external fiber.

Coupled cavity



fiber with negative dispersion ($\text{GDD} < 0$)

soliton pulse compression in coupled cavity with shortens
pulse in main cavity

1989

January 1, 1989 / Vol. 14, No. 1 / OPTICS LETTERS 39

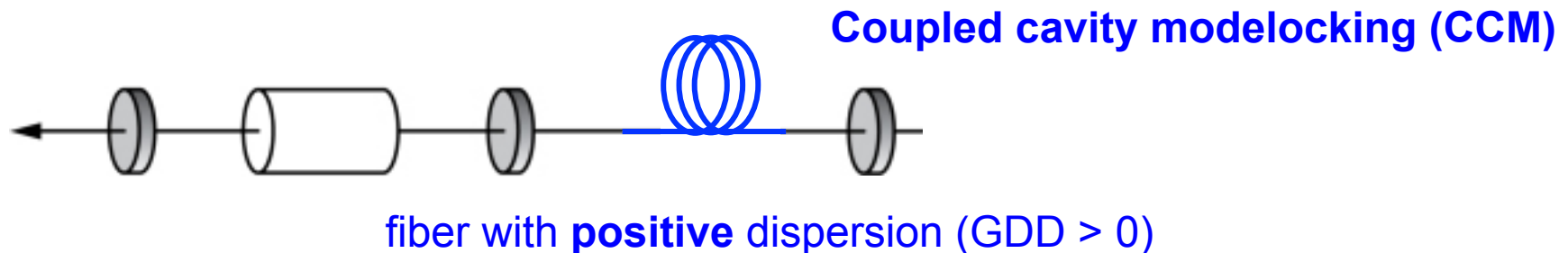
Enhanced mode locking of color-center lasers

P. N. Kean, X. Zhu, D. W. Crust, R. S. Grant, N. Langford, and W. Sibbett

Department of Physics and Astronomy, University of St. Andrews, St. Andrews, Fife KY16 9SS, Scotland

Received July 18, 1988; accepted October 14, 1988

A significant enhancement in the mode locking of a KCl:Ti color-center laser has been observed when a length of optical fiber having positive group-velocity dispersion was incorporated within an external control cavity. Pulse durations of ~ 260 fsec were obtained by this method, representing a compression factor $\sim 60\times$ that with the color-center laser alone. Similar results have also been observed with an InGaAsP semiconductor diode amplifier as the nonlinear element within the control cavity.



Dispersive pulse broadening in coupled cavity! How should that shorten pulse in main cavity?

Explanation with **APM (additive pulse modelocking)**:

E. P. Ippen, H. A. Haus, L. Y. Liu, *J. Opt. Soc. Am. B* **6**, 1736, 1989

Pulse is broadened yes, ... but SPM makes an intensity dependent phase shift, which leads to constructive interference at the peak and destructive interference in the wings with the pulse from the main cavity. This gives a pulse shortening effect of the coupled cavity.

1988

K. J. Blow and D. Wood

Vol. 5, No. 3/March 1988/J. Opt. Soc. Am. B 629

Mode-locked lasers with nonlinear external cavities

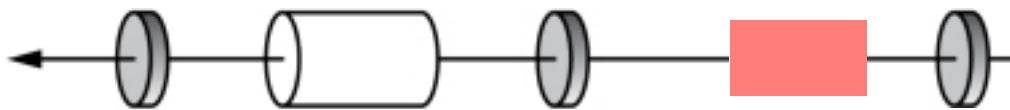
K. J. Blow and David Wood

British Telecom Research Laboratories, Martlesham Heath, Ipswich IP5 7RE, UK

Received August 31, 1987; accepted November 9, 1987

A nonlinear element, when introduced into an external cavity, is shown to improve the mode locking of lasers. Mode locking is achieved by inducing coupling between the cavity modes, thus permitting more efficient transmission of phase information. We begin by discussing a phenomenological laser model for homogeneously broadened systems. The model laser is coupled to an external cavity and contains a nonlinear element. The returning pulse from this external cavity is then mixed with a circulating pulse in the laser at the output mirror. We have considered two nonlinear elements, a saturable absorber and a saturable amplifier. Although these elements have quite different pulse-shaping effects, they both cause considerable improvement in mode-locked performance.

Coupled cavity



“any nonlinear element in the coupled cavity should shorten the pulse”
theoretical prediction with numerical modeling ... physical insight was missing

1990

December 1, 1990 / Vol. 15, No. 23 / OPTICS LETTERS 1377

Coupled-cavity resonant passive mode-locked Ti:sapphire laser

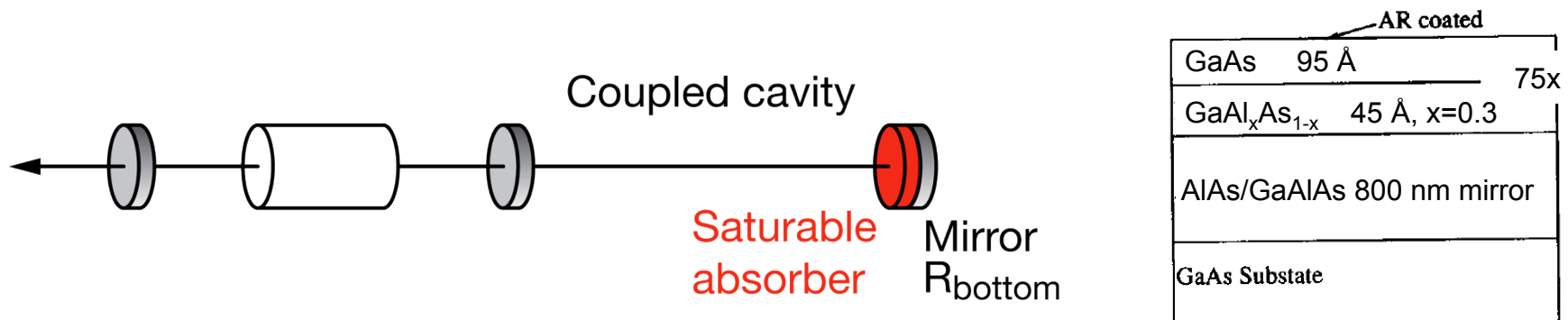
U. Keller, W. H. Knox, and H. Roskos

AT&T Bell Laboratories, Crawford's Corner Road, Holmdel, New Jersey 07733

Received June 21, 1990; accepted September 26, 1990

We use a nonlinear quantum-well reflective sample in a coupled-cavity configuration for resonant passive mode locking of a Ti:sapphire laser, producing tunable pulses as short as 2 psec. Pulses of less than 10-psec duration are observed over a 50-nm wavelength tuning range using a single-quantum-well reflector, over approximately 2 mm of external cavity length detuning. Stable mode-locked pulse trains are obtained without active cavity length control; however, the optical spectrum depends on the phase. We generate up to the sixth harmonic of the fundamental repetition rate, at 1.2 GHz, by simply decreasing the external cavity length.

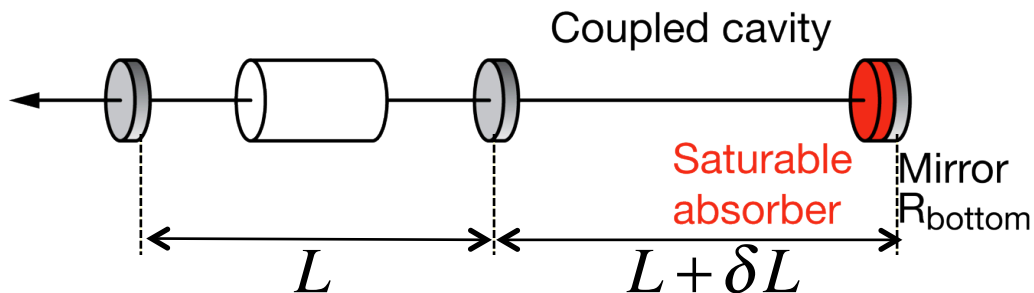
Resonant passive modelocking (RPM)



semiconductor saturable absorber (*"borrowed from my office neighbour Keith Goosen"*)
 pulse compression in coupled cavity which shortens pulse in main cavity

1990

Resonant passive modelocking (RPM)



Surprise:

- no active cavity length stabilization was necessary
- modelocking was stable even with large cavity length detuning δL

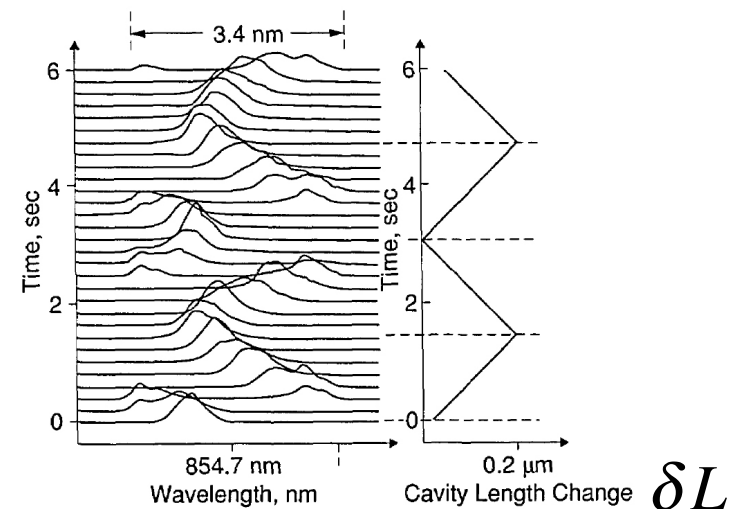
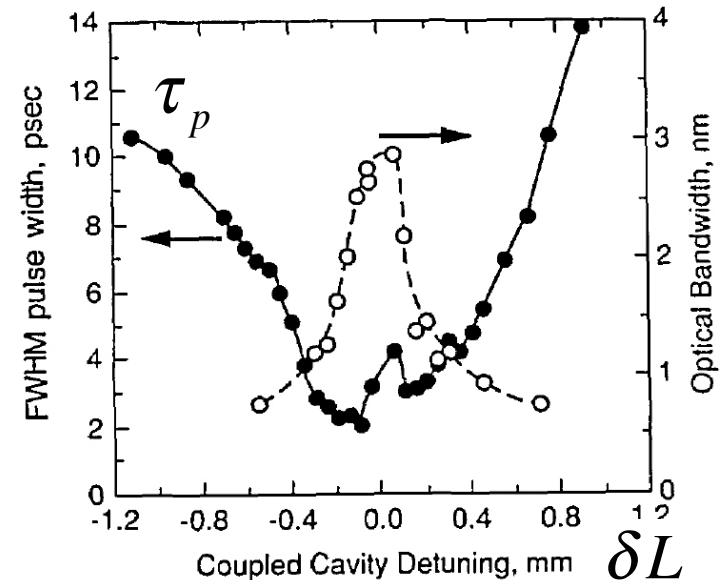
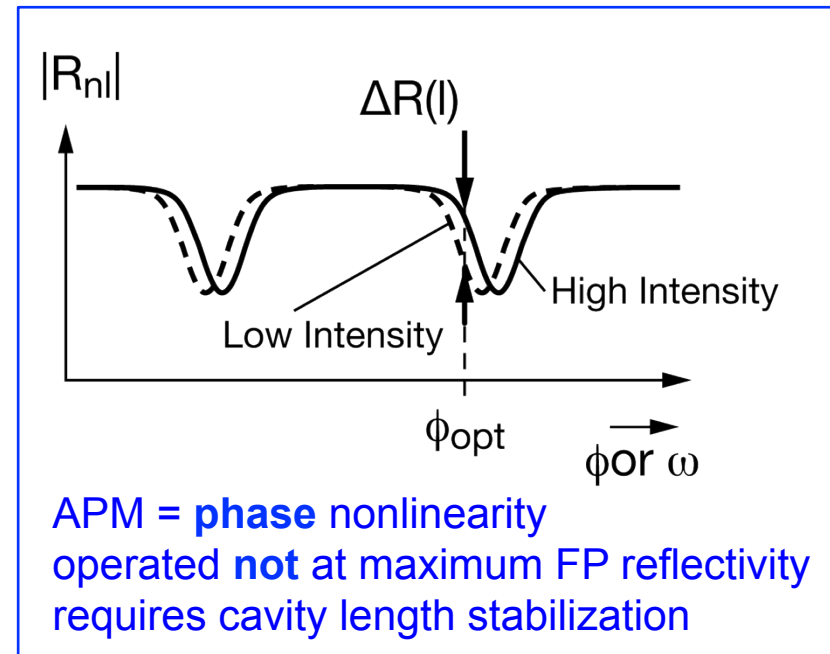
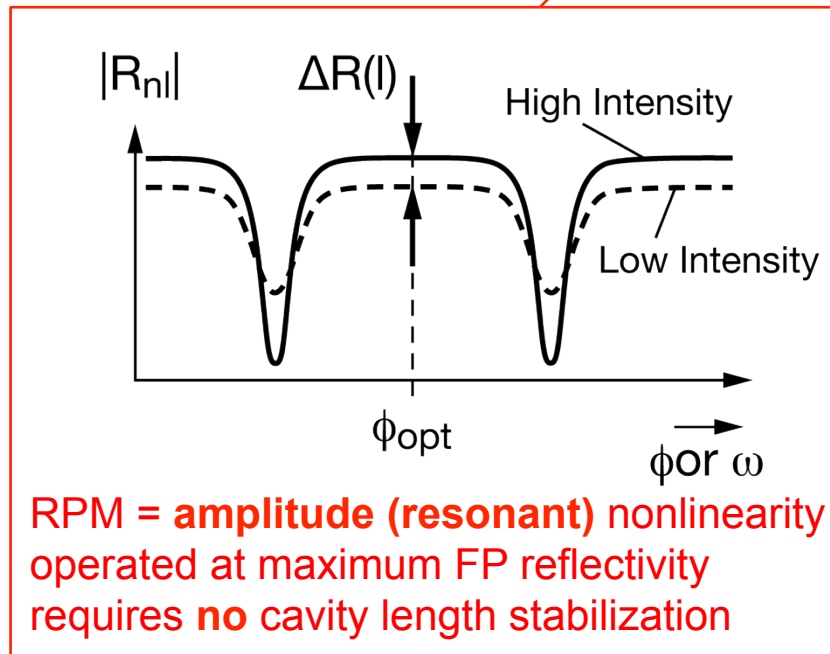
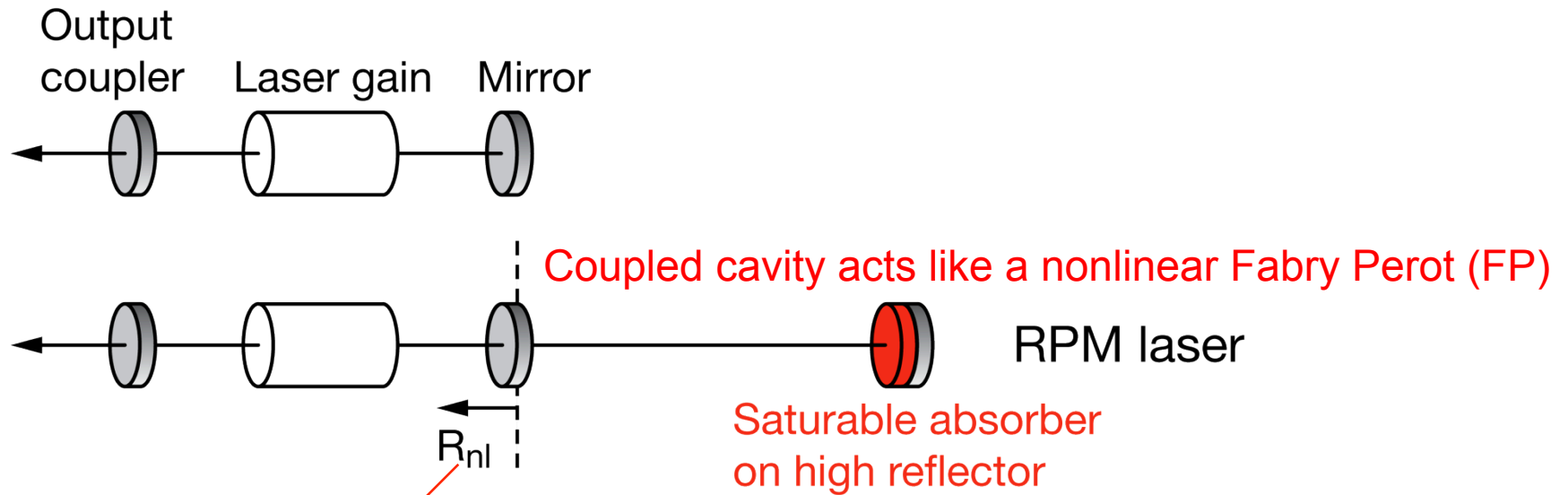


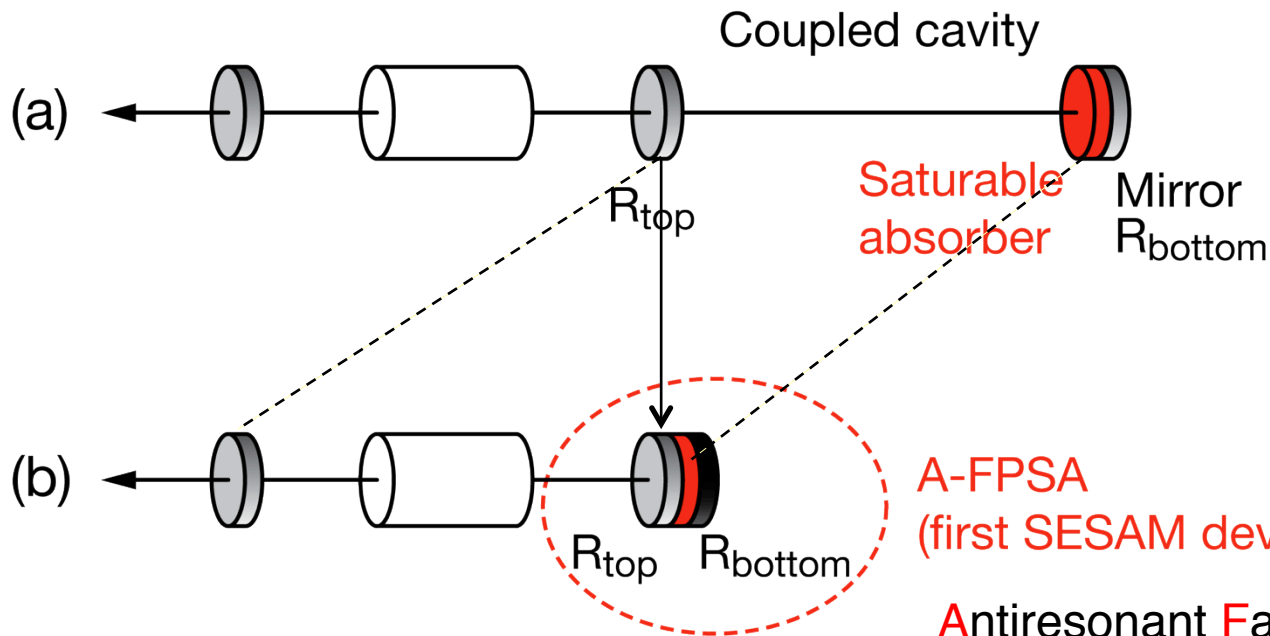
Fig. 3. Optical self-frequency shift versus the external cavity length detuning that ensures coherent superposition of the pulses at the coupling mirror.

U. Keller et al., *Optics Lett.* **15**, 1377, 1990

ETH Coupled Cavity Modelocking by Ursula Keller



ETH Invention of the first SESAM device: A-FPSA



Antiresonant Fabry-Perot Saturable Absorber (A-FPSA)
 Example: *Opt. Lett.* **18**, 217, 1993

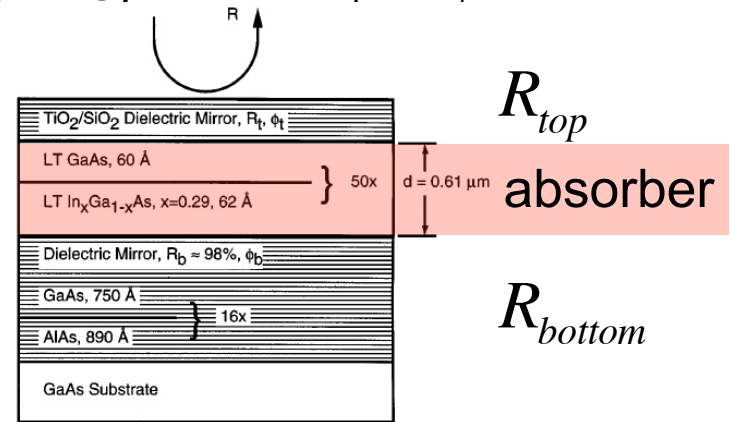
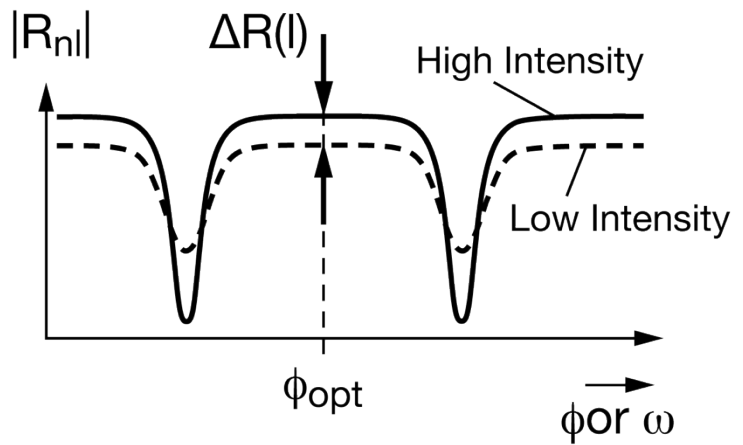


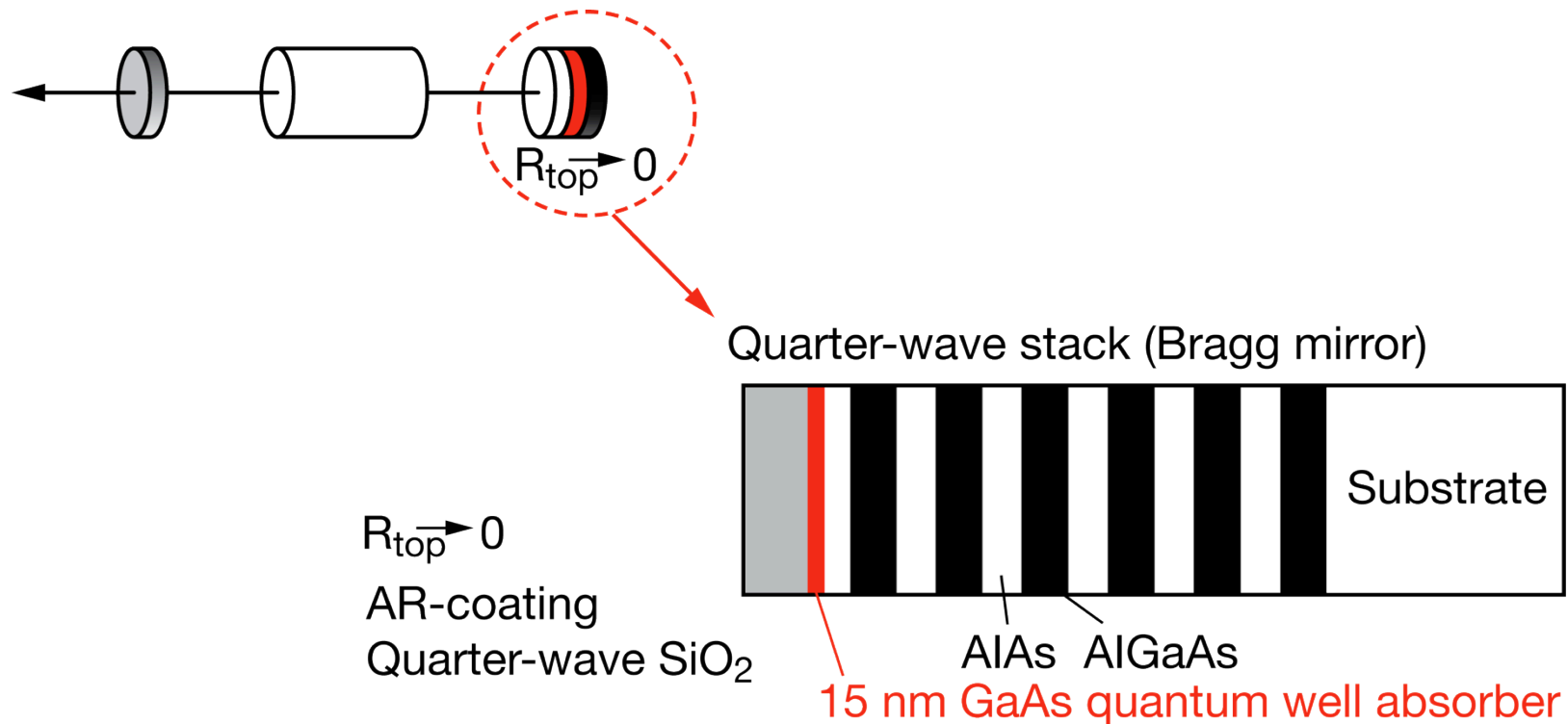
Fig. 1. Structure of an A-FPSA designed for an operation wavelength of $\approx 1 \mu\text{m}$.

U. Keller et al., *Optics Lett.* **17**, 505, 1992

ETH Scaling A-FPSA towards a single QW SESAM

1995

Adjustable parameter: top reflector



Single 15 nm GaAs quantum well embedded inside a Bragg mirror

L. R. Brovelli et al., *Electron. Lett.*, vol. 31, 287, 1995

1996

IEEE JOURNAL OF SELECTED TOPICS IN QUANTUM ELECTRONICS, VOL. 2, NO. 3, SEPTEMBER 1996

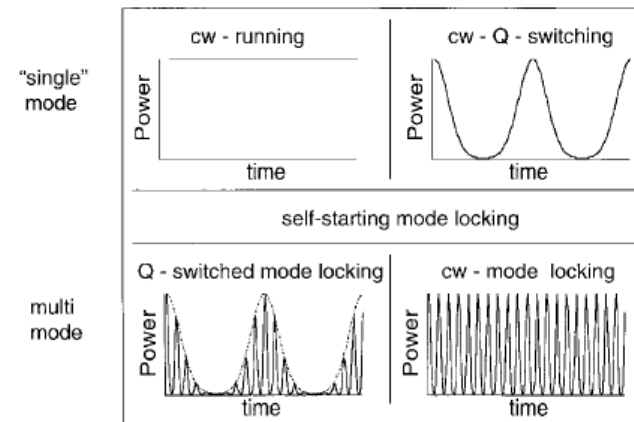
435

Semiconductor Saturable Absorber Mirrors (SESAM's) for Femtosecond to Nanosecond Pulse Generation in Solid-State Lasers

Ursula Keller, *Member, IEEE*, Kurt J. Weingarten, *Member, IEEE*, Franz X. Kärtner, Daniel Kopf, Bernd Braun, Isabella D. Jung, Regula Fluck, Clemens Hönninger, Nicolai Matuschek, and Juerg Aus der Au

(Invited Paper)

Abstract—Intracavity semiconductor saturable absorber mirrors (SESAM's) offer unique and exciting possibilities for passively pulsed solid-state laser systems, extending from *Q*-switched pulses in the nanosecond and picosecond regime to mode-locked pulses from 10's of picoseconds to sub-10 fs. This paper reviews the design requirements of SESAM's for stable pulse generation in both the mode-locked and *Q*-switched regime. The combination of device structure and material parameters for SESAM's provide sufficient design freedom to choose key parameters such as recovery time, saturation intensity, and saturation fluence, in a compact structure with low insertion loss. We have been able to demonstrate, for example, passive modelocking (with no *Q*-switching) using an intracavity saturable absorber in solid-state lasers with long upper state lifetimes (e.g., 1- μ m neodymium transitions), Kerr lens modelocking assisted with pulsewidths as short as 6.5 fs from a Ti:sapphire laser—the shortest pulses ever produced directly out of a laser without any external pulse compressor, and passive *Q*-switching with pulses as short as



it modes of operation of a laser with a saturable absorber. ; typically occurs with much longer pulses and lower pulse han CW mode-locking.

, *Q*-switched modelocking behavior [5]–[9]. In inductor absorbers have an intrinsic bitemporal

Introduction of the ackronym: SESAM
 Invited review article
 September 1996, IEEE JSTQE

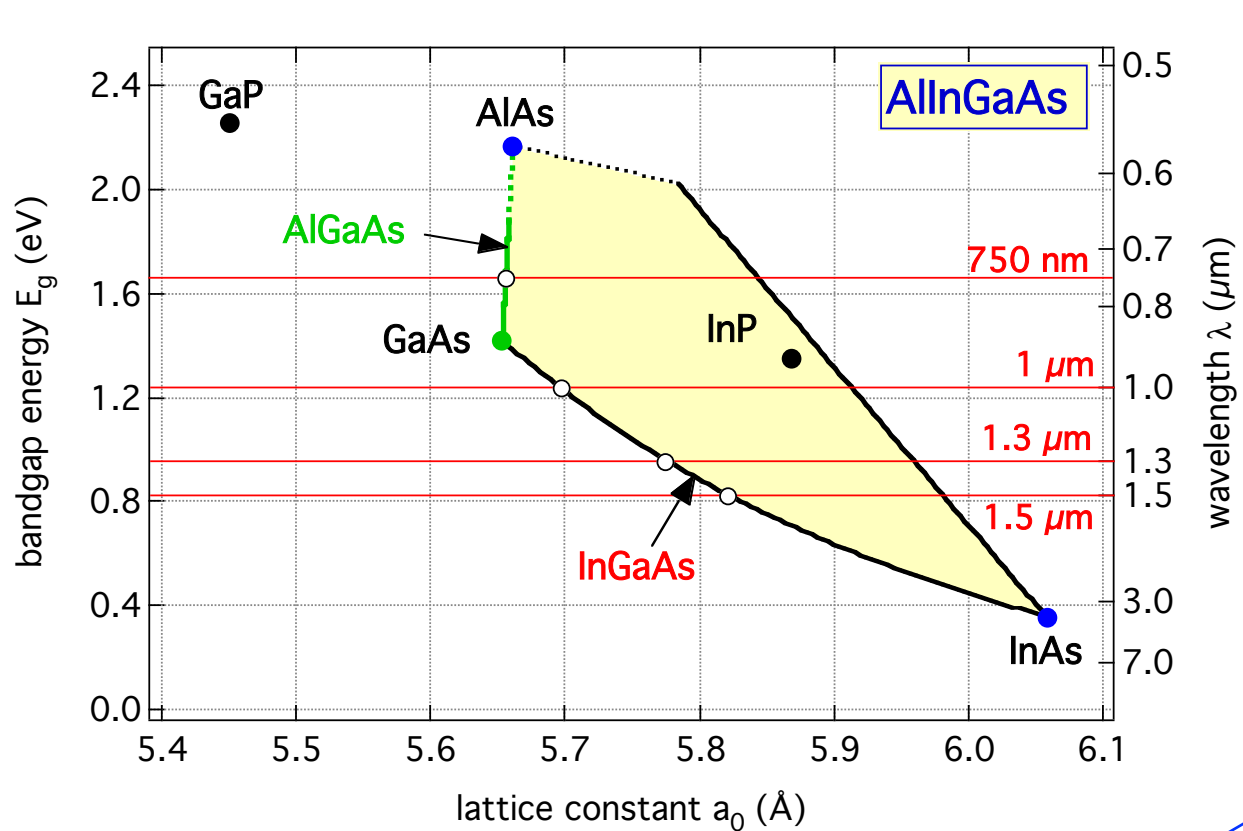
Moving from Ti:sapphire to diode-pumped ss-laser

was not trivial why?

Ti:sapphire laser

@ 800 nm

Opt. Lett. **15**, 1377, 1990



AR coated

GaAs	95 Å	75x
GaAl _x As _{1-x}	45 Å, x=0.3	
AlAs/GaAlAs 800 nm mirror		
GaAs Substrate		

Nd:YLF laser

@ 1.064 μm

IEEE JQE **28**, 1710, 1992

AR coated

LT GaAs	60 Å	50x
LT In _x Ga _{1-x} As	62 Å, x=0.29	
GaAs/AlAs 1.06 μm mirror		
GaAs Substrate		

LT = low temperature
MBE growth

Moving from Ti:sapphire to diode-pumped ss-laser

390 OPTICS LETTERS / Vol. 16, No. 6 / March 15, 1991

Coupled-cavity resonant passive mode-locked Nd:yttrium lithium fluoride laser

U. Keller and T. K. Woodward

AT&T Bell Laboratories, Holmdel, New Jersey 07733

D. L. Sivco and A. Y. Cho

AT&T Bell Laboratories, Murray Hill, New Jersey 07974

1991

RPM modelocked Nd:YLF

April 1, 1992 / Vol. 17, No. 7 / OPTICS LETTERS 505

Solid-state low-loss intracavity saturable absorber for Nd:YLF lasers: an antiresonant semiconductor Fabry-Perot saturable absorber

U. Keller, D. A. B. Miller, G. D. Boyd, T. H. Chiu, J. F. Ferguson, and M. T. Asom

AT&T Bell Laboratories, Crawfords Corner Road, Holmdel, New Jersey 07733

1992

A-FPSA modelocked Nd:YLF
Nd:YLF laser pumped with
Ti:sapphire laser

640 OPTICS LETTERS / Vol. 18, No. 8 / April 15, 1993

Passively mode-locked diode-pumped solid-state lasers that use an antiresonant Fabry-Perot saturable absorber

K. J. Weingarten

Lightwave Electronics Corporation, 1161 San Antonio Road, Mountain View, California 94043

U. Keller, T. H. Chiu, and J. F. Ferguson

AT&T Bell Laboratories, Crawfords Corner Road, Holmdel, New Jersey 07733

1993

“mailed A-FPSA to California”

A-PFSA modelocked
diode-pumped Nd:YLF and
Nd:YAG laser

1993

1532 OPTICS LETTERS / Vol. 18, No. 18 / September 15, 1993

Self-starting diode-pumped femtosecond Nd fiber laser

M. H. Ober and M. Hofer

Abteilung Quantenelektronik, Technische Universität Wien, Gusshausstrasse 27/359/4, A-1040 Vienna, Austria

U. Keller

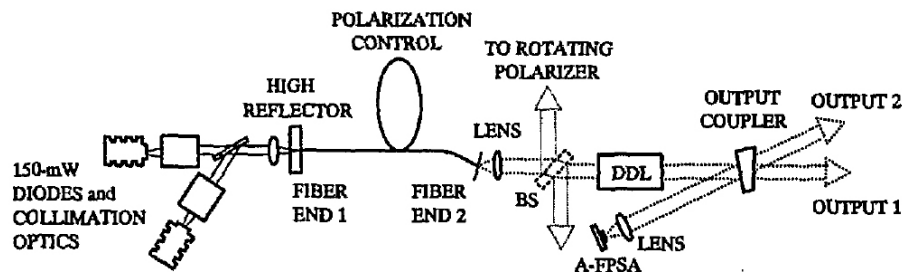
Institute of Quantum Electronics, Swiss Federal Institute of Technology (ETH), CH-8093 Zürich, Switzerland

T. H. Chiu

AT&T Bell Laboratories, Crawfords Corner Road, Holmdel, New Jersey 07701

Received March 26, 1993

A self-starting passively mode-locked diode-pumped neodymium fiber laser with a semiconductor antiresonant Fabry–Perot saturable absorber (A-FPSA) is demonstrated for the first time to our knowledge. Mode locking can be initiated and maintained by the semiconductor absorber, and pulse durations down to 260 fs are routinely obtained. Alternatively, shorter pulses (60 fs) were generated by exploitation of nonlinear polarization evolution in the fiber (in combination with a stronger pump source) where the A-FPSA simply initiates the pulse-forming process.



“carried an A-FPSA to TU Vienna”

LT grown SESAMs to reduce absorber recovery time

February 1, 1993 / Vol. 18, No. 3 / OPTICS LETTERS 217

Self-starting and self-Q-switching dynamics of passively mode-locked Nd:YLF and Nd:YAG lasers

U. Keller, T. H. Chiu, and J. F. Ferguson

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Received August 12, 1992

The semiconductor antiresonant Fabry-Perot saturable absorber (A-FPSA) has a bitemporal absorption response with a slow time component that is due to carrier recombination and a fast time component that is due to intraband thermalization. We demonstrate that the slow component provides the self-starting mechanism and without significant Kerr lens contribution the fast component is necessary for steady-state pulse formation in passively cw mode-locked solid-state lasers. The carrier lifetime of the bitemporal A-FPSA was varied by the molecular-beam-epitaxy growth temperature to characterize its inf switching dynamics of cw mode-locked Nd:YLF and Nd:YAG lasers. The reflector of the A-FPSA can be adjusted to optimize the self-starting performance of cw mode-locked solid-state lasers.

Adjustable parameter:
absorber recovery time

More on **LT MBE growth** and **ion implantation** to reduce recovery time of SESAMs:

Appl. Phys. Lett., vol. 75, pp. 1437-1439, 1999

Appl. Phys. Lett., vol. 74, pp. 1993-1995, 1999

Appl. Phys. Lett., vol. 74, 3134-3136, 1999

Appl. Phys. Lett., vol. 74, pp. 1269-1271, 1999

Physica B: Condensed Matter, vol. 273-274, pp. 733-736, 1999

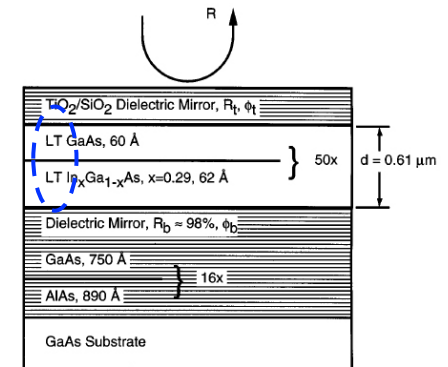
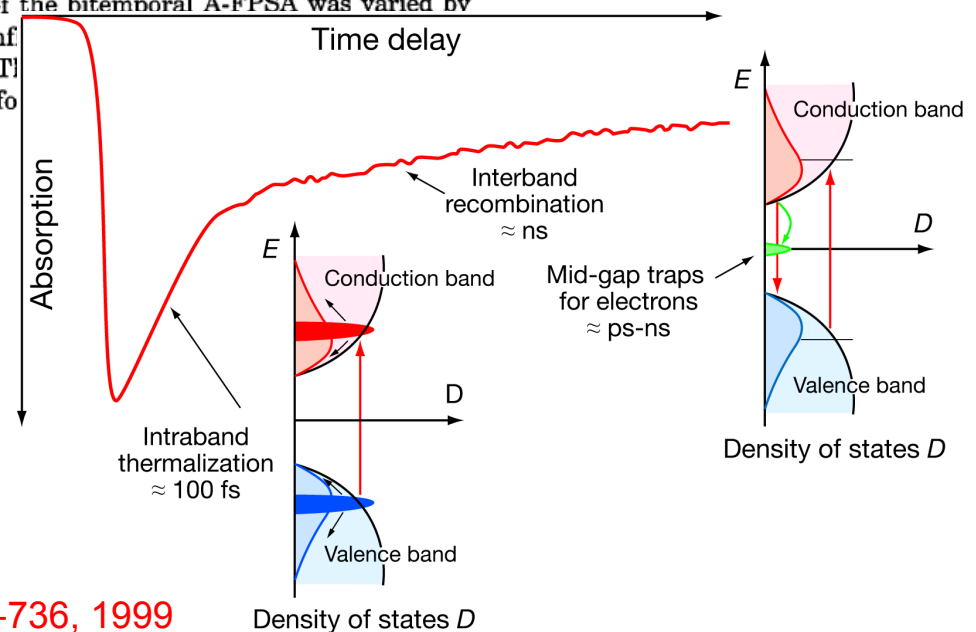
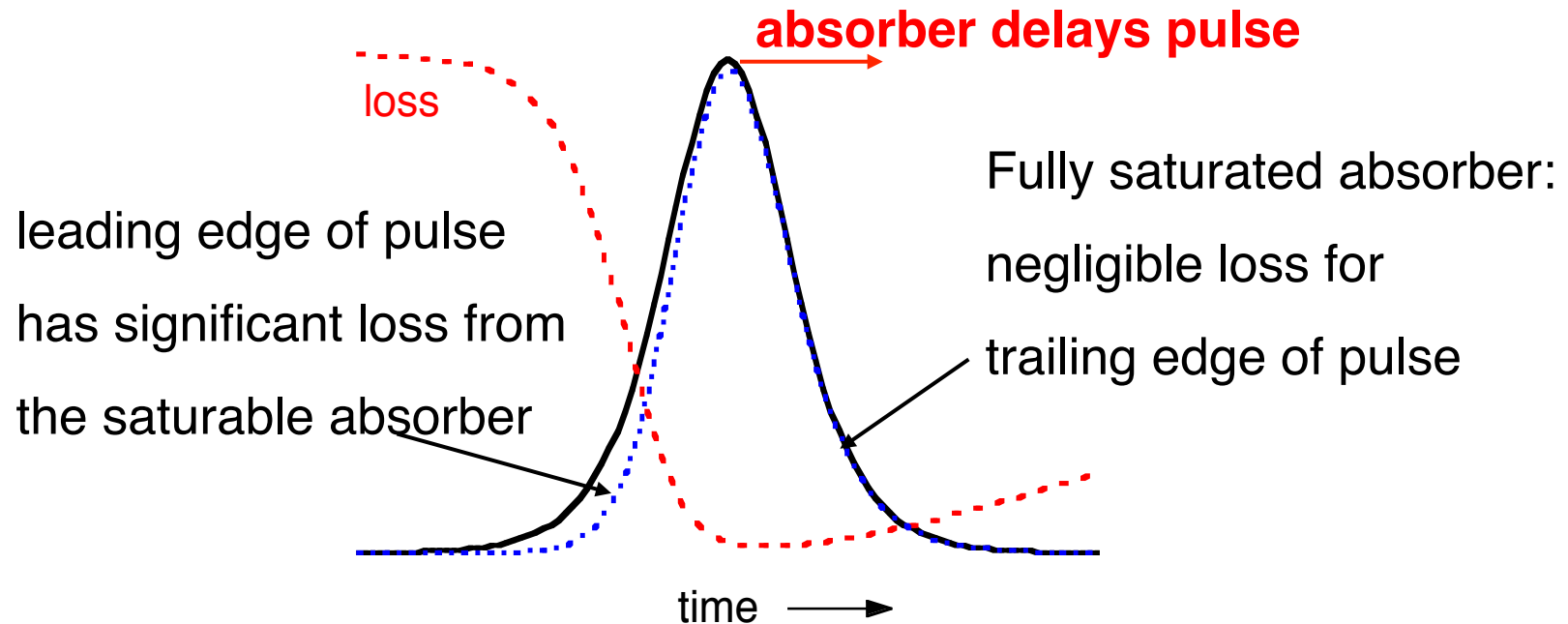


Fig. 1. Structure of an A-FPSA designed for an operation wavelength of $\approx 1 \mu\text{m}$.



Stable pulses even with a “long” net gain window

R. Paschotta, U. Keller, *Appl. Phys. B* **73**, 653, 2001



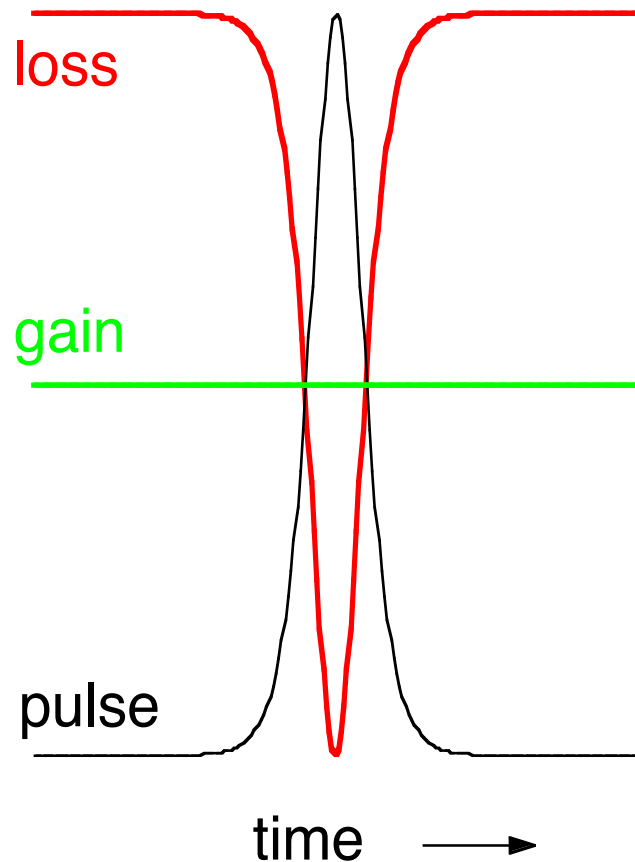
Dominant stabilization process with a relatively long net-gain window:

Picosecond domain: absorber delays pulse

The pulse is constantly moving backward and can swallow any noise growing behind itself.

Femtosecond domain: dispersion in soliton modelocking

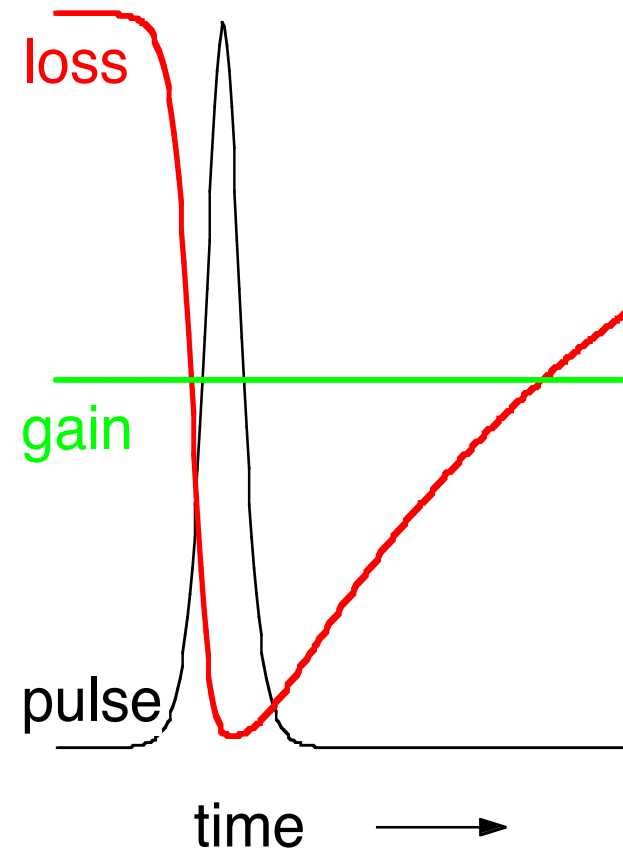
Stable pulses even with a “long” net gain window



Kerr lens modelocking (KLM)

Fast saturable absorber

D. E. Spence, P. N. Kean, W. Sibbett
Opt. Lett. **16**, 42, 1991



Soliton modelocking

“not so fast” saturable absorber

F. X. Kärtner, U. Keller,
Opt. Lett. **20**, 16, 1995



Q-switched mode locking is avoided if...

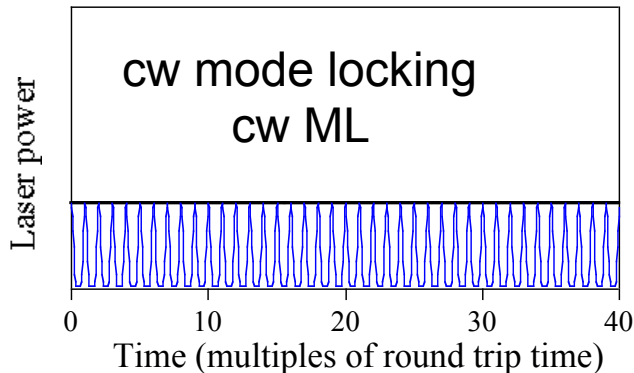
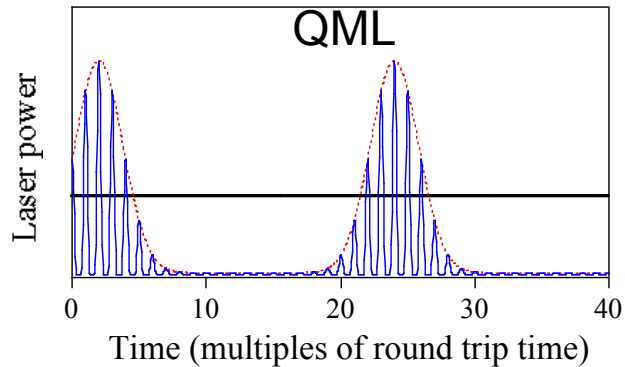
C. Hönninger, R. Paschotta, F. Morier-Genoud, M. Moser, and U. Keller,
JOSA B **16**, 46 (1999)

$$E_P^2 > E_{\text{sat,L}} E_{\text{sat,A}} \Delta R$$

QML noise

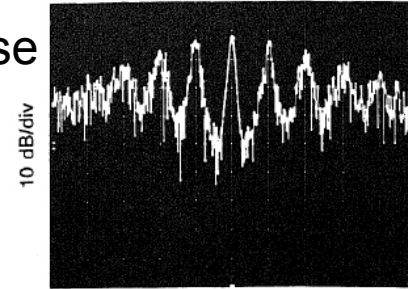
$$= A_{\text{eff,A}} F_{\text{sat,A}} \Delta R$$

Q-switched mode locking



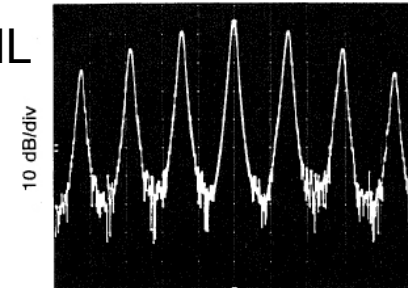
MICROWAVE SPECTRUM ANALYZER

(a) PUMP POWER 0.6W



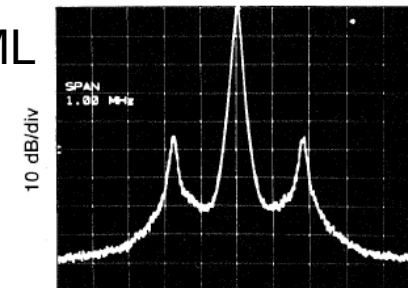
(b) PUMP POWER 1.4W

QML



(c) PUMP POWER 2W

cw ML



CENTER FREQUENCY 219.4 MHz
 SPAN 1 MHz, RES BW 10 kHz

Appl. Phys. B **58**, 347, 1994

2005


1) SESAMs with low saturation fluence:

Appl. Phys. B 81, 27–32 (2005)

DOI: 10.1007/s00340-005-1879-1

Applied Physics B

Lasers and Optics

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Semiconductor saturable absorber mirror structures with low saturation fluence

¹ETH Zurich, Physics Department, Institute of Quantum Electronics, Wolfgang-Pauli-Strasse 16, 8093 Zürich, Switzerland

²Time-Bandwidth Products, GigaTera Product Group, Technoparkstr. 1, 8005 Zürich, Switzerland


2) SESAMs with inverse saturable absorption:

Appl. Phys. B 80, 151–158 (2005)

DOI: 10.1007/s00340-004-1622-3

Applied Physics B

Lasers and Optics

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New regime of inverse saturable absorption for self-stabilizing passively mode-locked lasers

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ETH All-optical 100-GHz pulse generation at 1.5 μm

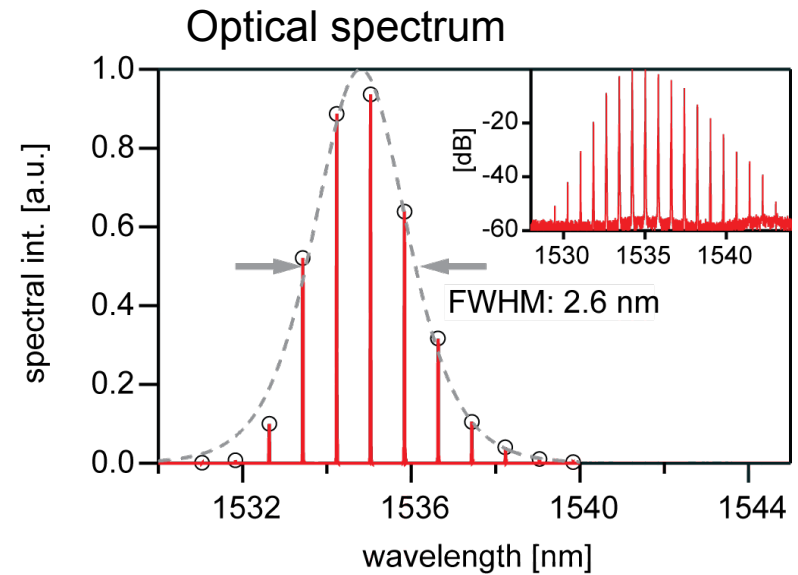
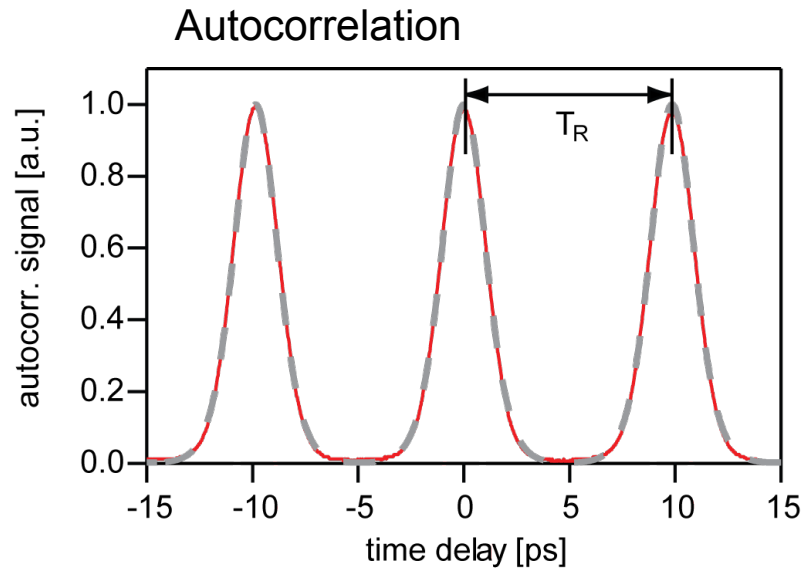
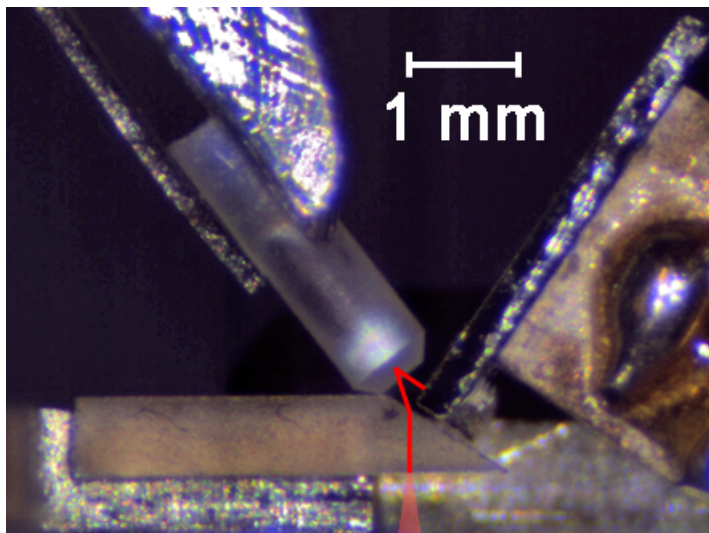


Photo of actual setup



Pulse repetition rate: 101 GHz
Max. output-power: 35 mW
Optical bandwidth: 2.6 nm
Pulse width: 1.6 ps
(1.7x time-bandwidth limit)

A. E. H. Oehler et al., Opt. Express **16**, 21930, 2008

SESAMs for High-Power Oscillators: Design Guidelines and Damage Thresholds

Clara J. Saraceno, Cinia Schriber, Mario Mangold, Martin Hoffmann, Oliver H. Heckl, Cyrill R. E. Baer, Matthias Golling, Thomas SÜdmeyer, and Ursula Keller

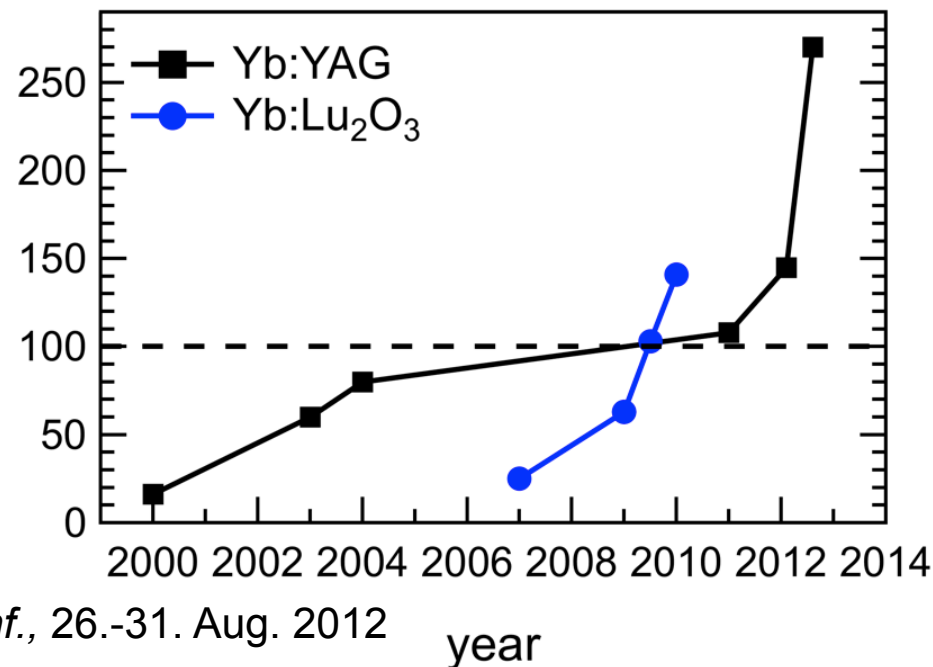
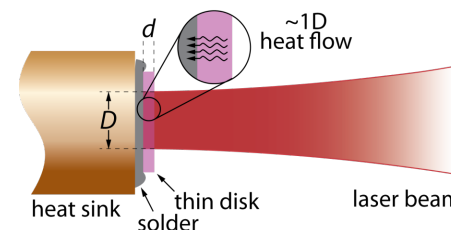
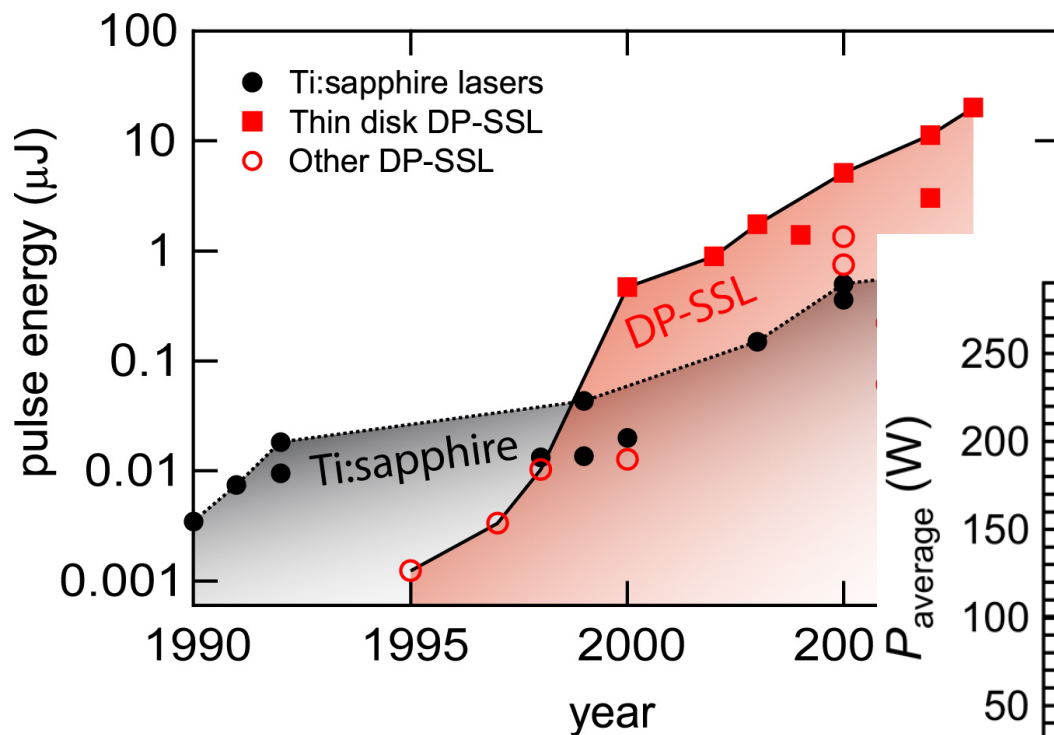
(Invited Paper)

Abstract—We present for the first time to the best of our knowledge a systematic study of lifetime and damage of semiconductor saturable absorber mirrors (SESAMs) designed for operation in high-power oscillators. We characterize and compare nonlinear reflectivity and inverse saturable absorption (ISA) parameters as well as damage threshold and lifetime of different representative SESAMs under test using a nonlinear reflectivity measurement setup at unprecedented high fluence levels. We investigate the catastrophic damage that occurs at very high fluences by demonstrating a dependence of the damage threshold on the ISA parameter F_2 and the maximum reflectivity fluence F_0 . We can clearly demonstrate that the damage fluence F_d scales proportionally to $\sqrt{F_2}$ for all SESAMs. In the case of SESAMs with the same absorber where the product $F_{\text{sat}} \cdot \Delta R$ is constant, the damage fluence F_d scales proportionally to F_0 . Therefore, damage occurs due to heating of the lattice by the energy absorbed due to the ISA process and is not related to the quantum well (QW) absorbers. Furthermore, we present guidelines on how to design samples with high saturation fluences, reduced induced absorption, and high damage thresholds. Using multiple QWs and a suitable dielectric topsection, we achieved SESAMs with saturation fluences $>200 \mu\text{J}/\text{cm}^2$, nonsaturable losses $<0.1\%$, and reduced ISA. Our best sample could not be damaged at a maximum available fluence of $0.21 \text{ J}/\text{cm}^2$ and a peak intensity of $370 \text{ GW}/\text{cm}^2$. These SESAMs will be suitable for future high-power femtosecond oscillators in the kilowatt average output power regime, which is very interesting for attosecond science and industrial material processing applications.

various fields, such as physics, chemistry, biology, materials science, imaging, material processing, communication, and medicine. The invention of the semiconductor saturable absorber mirror (SESAM) [3], [4] nearly 20 years ago was a major advancement for the development of simple and reliable ultrafast laser systems. It enabled the first stable and self-starting passive modelocking of diode-pumped solid-state lasers (DPSSLs), resolving the long-standing Q-switching problem [5]. Today, SESAMs have become key devices for modelocking of numerous laser types, including DPSSLs, fiber lasers, and semiconductor lasers. Semiconductors are ideally suited as saturable absorbers because they can cover a broad wavelength range and yield short recovery times, supporting the generation of picosecond to femtosecond pulse durations. The macroscopic nonlinear optical parameters for modelocking can be optimized over a wide range by the design of the mirror structure and the choice of the semiconductor absorber.

SESAM modelocking is currently the best-suited technology for high-power ultrafast laser oscillators. Recent SESAM modelocked thin-disk lasers have achieved average powers $>140 \text{ W}$ [6] and pulse energies $>25 \mu\text{J}$ [7], which are higher than for any other ultrafast oscillator technology. The combination of high power levels and multimegahertz repetition rates makes these lasers highly attractive for areas such as high-field

High average power lasers



C. J. Saraceno et al.,
Opt. Express submitted Aug. 2012
 Postdeadline Paper, *Europhoton Conf.*, 26.-31. Aug. 2012

First time >10 μJ pulse energy from a SESAM modelocked Yb:YAG thin disk laser:
Opt. Express **16**, 6397, 2008 and CLEO Europe June 2007

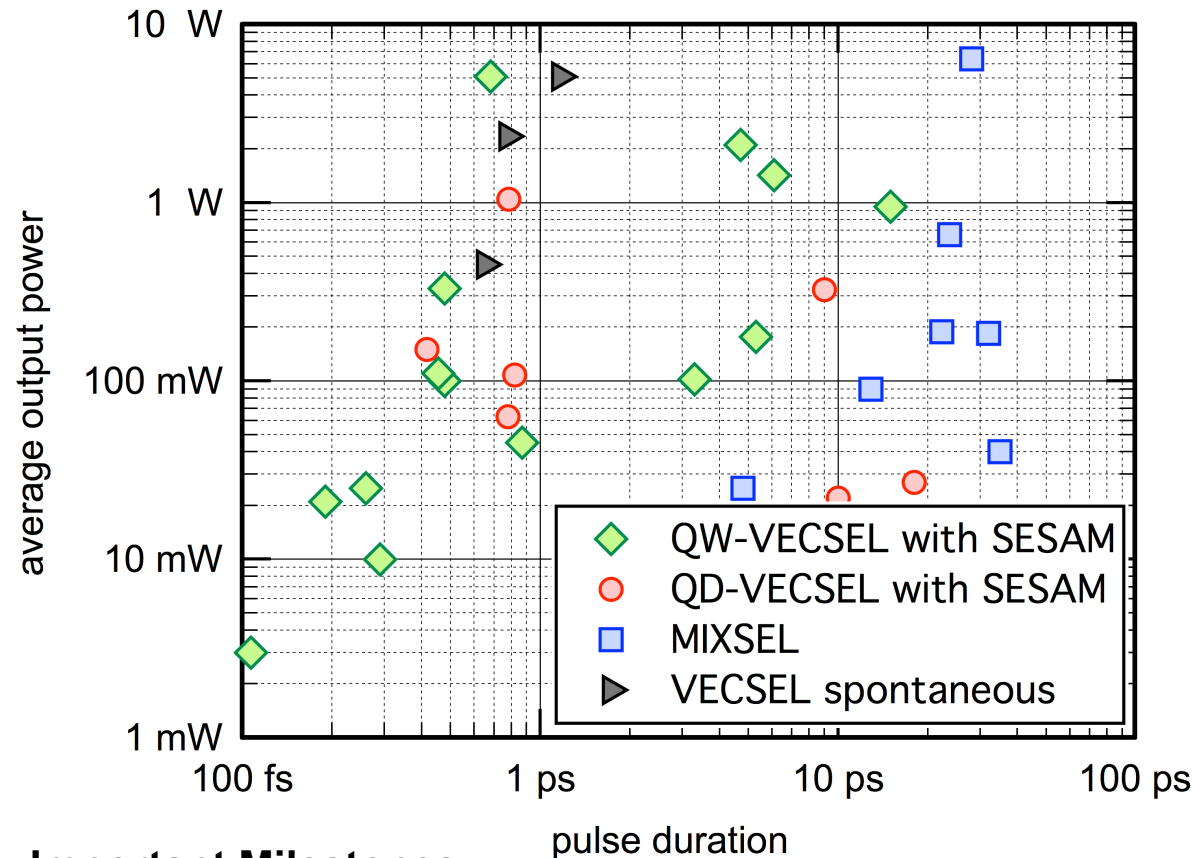
26 μJ with a multipass gain cavity and larger output coupling of 70% (Trumpf/Konstanz)
Opt. Express **16**, 20530, 2008

ETH Moving from ss-lasers to semiconductor lasers

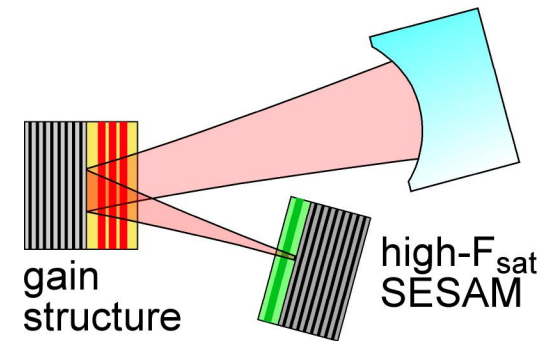
Vertical external cavity surface emitting laser (VECSEL)

Modelocked integrated external-cavity surface emitting laser (MIXSEL)

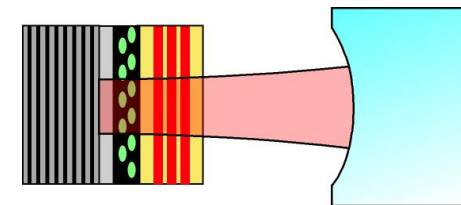
Appl. Phys. B, vol. 88, Nr. 4, pp. 493-497, 2007



Modelocked VECSEL



MIXSEL



Important Milestones:

MIXSEL with 6.4 W average output power: *Opt. Express* **18**, 27582, 2010

femtosecond VECSEL with > 1 W average output power: *Opt. Express* **19**, 8108, 2011

SESAM technology – ultrafast lasers for industrial application

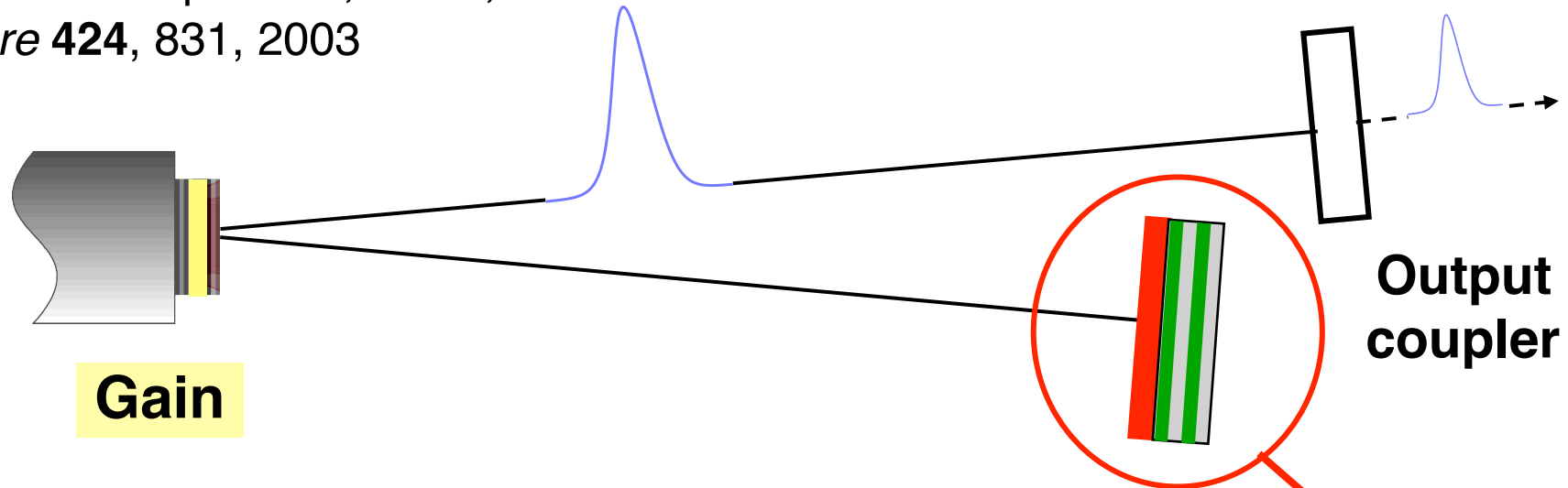
U. Keller et al. *Opt. Lett.* **17**, 505, 1992

IEEE JSTQE **2**, 435, 1996

Progress in Optics **46**, 1-115, 2004

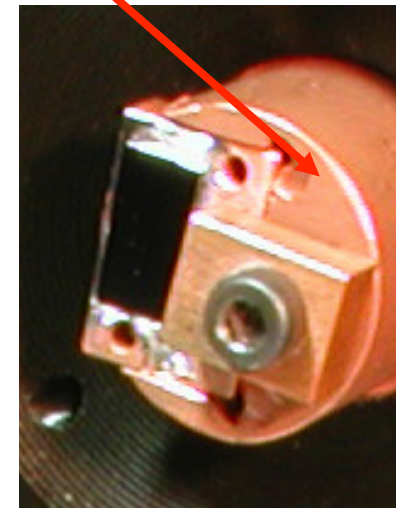
Nature **424**, 831, 2003

*SESAM solved Q-switching problem
for diode-pumped solid-state lasers*



SESAM
Semiconductor **S**aturable **A**bsorber **M**irror

self-starting, stable, and reliable modelocking of
diode-pumped ultrafast solid-state lasers



Thank you to Stanford, Bell Labs and ETH Zurich



Eidgenössische Technische Hochschule Zürich
Swiss Federal Institute of Technology Zurich

Stanford University

Ph.D. student

1985-1989

laser physics

ultrafast measurement
techniques

microwave measurement
tools

Bell Labs, Holmdel

MTS

1989-1993

+ access to state-of-the-art
semiconductor materials (MBE)

Enabled interdisciplinary approach with the combination of solid-state lasers, semiconductor physics, and microwave measurement techniques.

ETH Zurich

tenured Professor in Physics

since 1993

+ resources to be fully
empowered

- Web page of Prof. Ursula Keller at ETH Zurich: <http://www.ulp.ethz.ch>
- All papers are available to download as PDFs:
<http://www.ulp.ethz.ch/publications/paper>
- SESAM milestones: <http://www.ulp.ethz.ch/research/Sesam>
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<http://www.ulp.ethz.ch/research/UltrafastSolidStateLasers>
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